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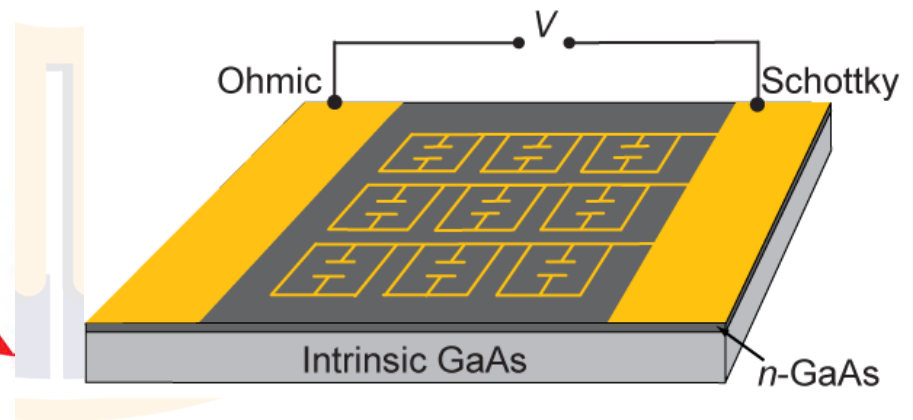
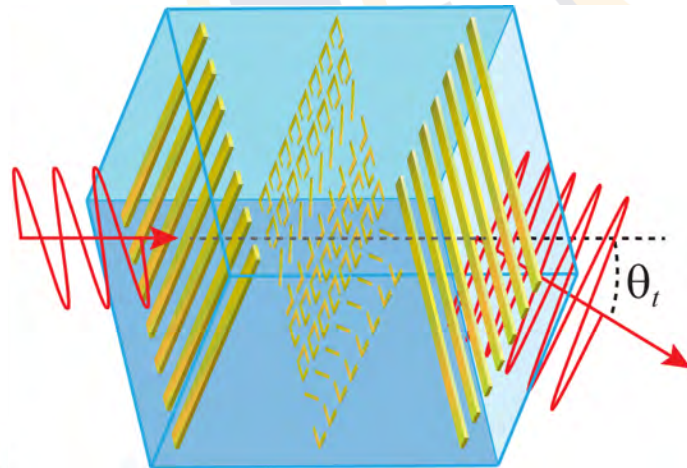
Seminar @ University of Notre Dame  
March 20, 2015

# Applying Metamaterials to Solve Terahertz Challenges

Hou-Tong Chen

*Center for Integrated Nanotechnologies*

*Los Alamos National Laboratory*





## Center for Nanoscale Materials Argonne National Laboratory

## Molecular Foundry Lawrence Berkeley National Laboratory



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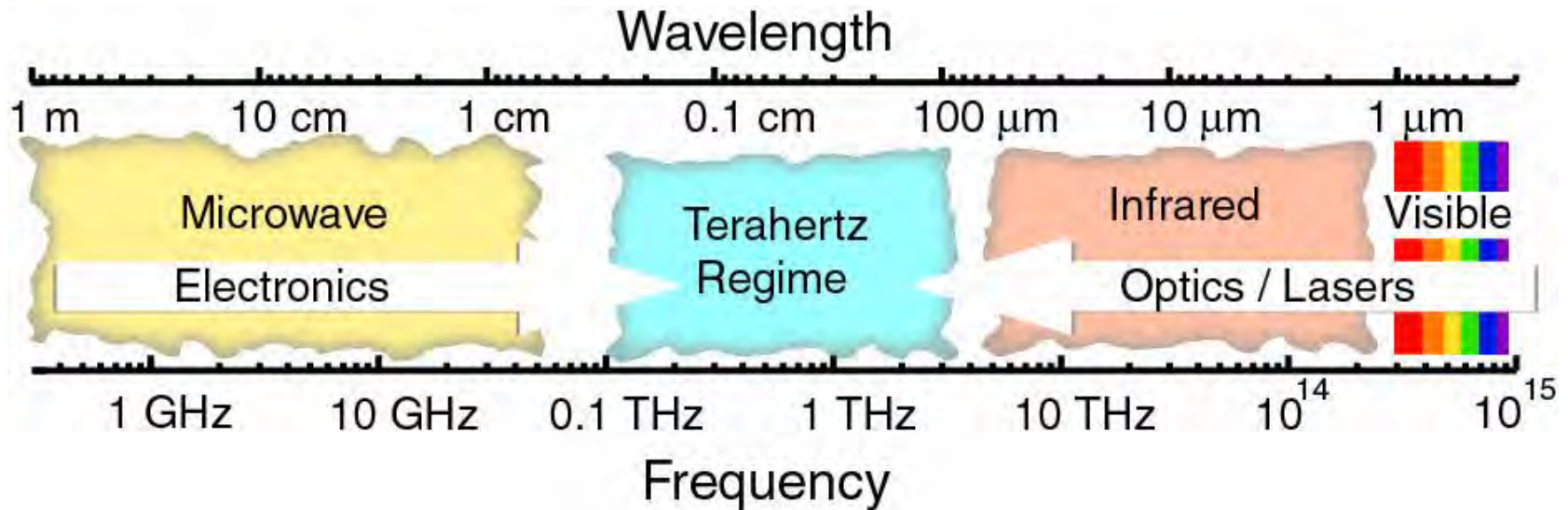
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## Center for Nanophase Materials Sciences Oak Ridge National Laboratory



# Challenges in THz Science and Technology

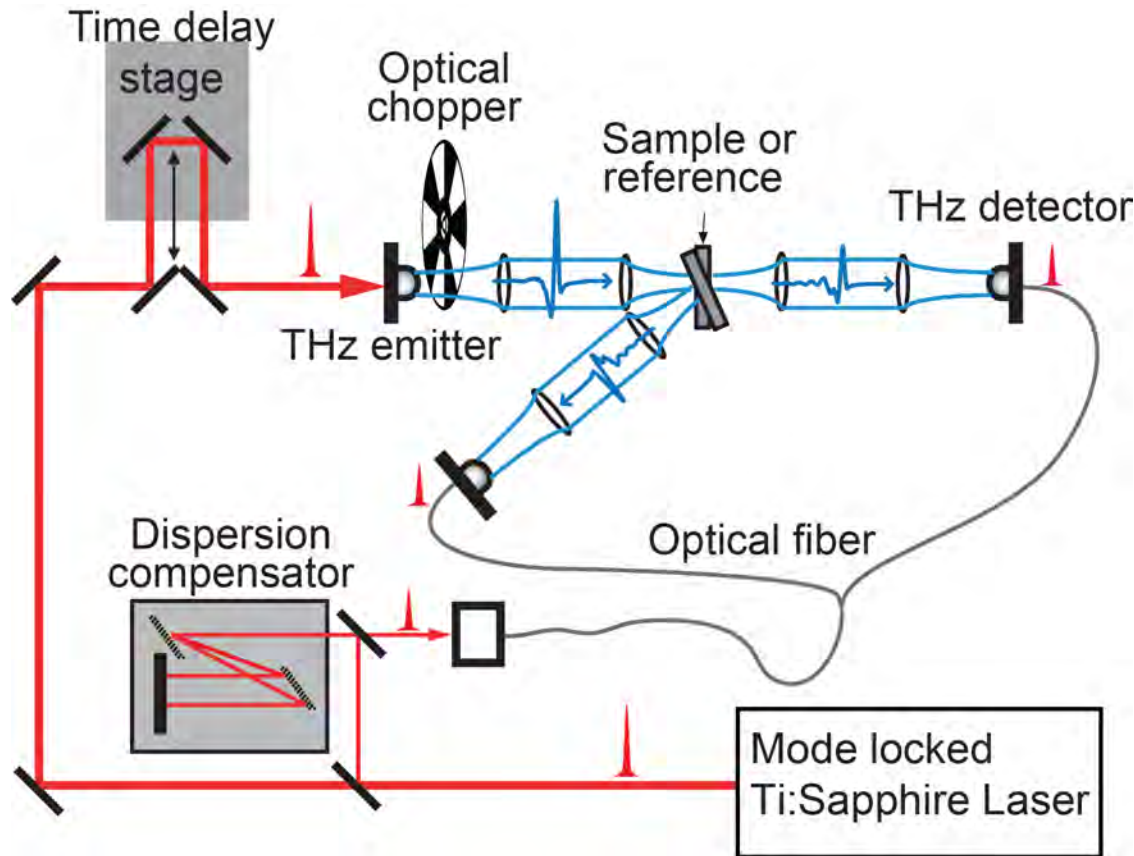


- ❑ THz is one of the least developed and most challenging regimes in the electromagnetic spectrum
- ❑ Functional THz devices and components are not widely available
- ❑ Metamaterials provide excellent opportunities in solving the material challenges associated with the “THz gap”



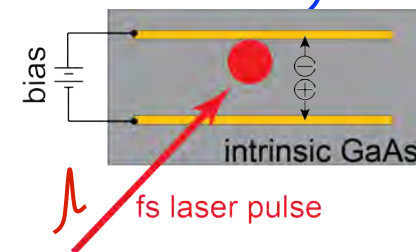
# Terahertz Generation and Detection

## Schematic of a THz time-domain spectrometer

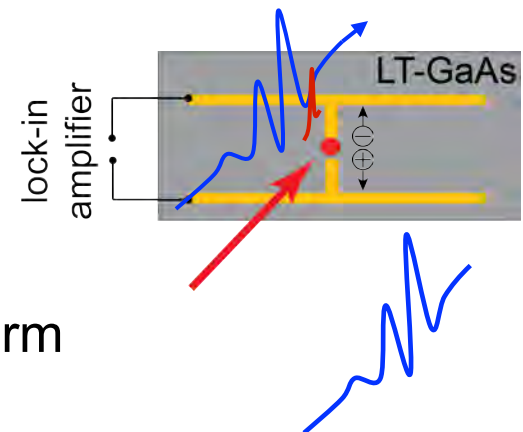


### THz generation:

$$E_{\text{THz}}(t) \propto \frac{\partial J(t)}{\partial t}$$



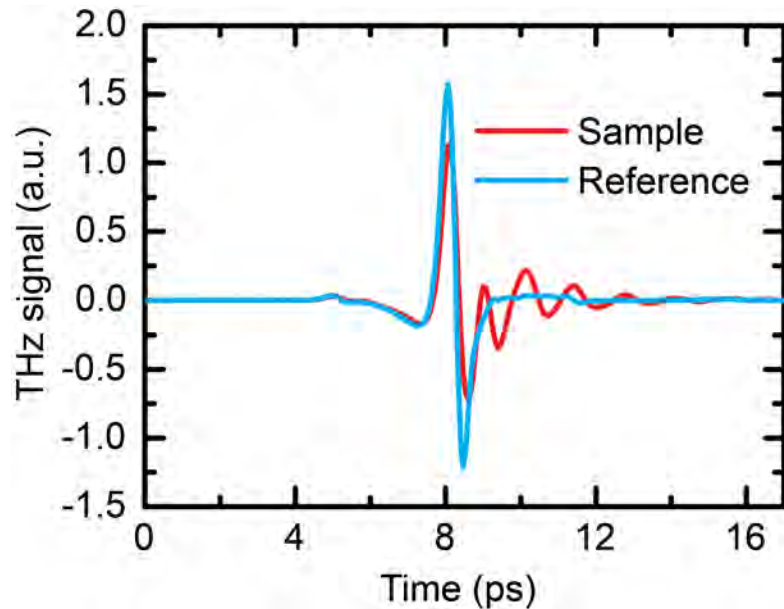
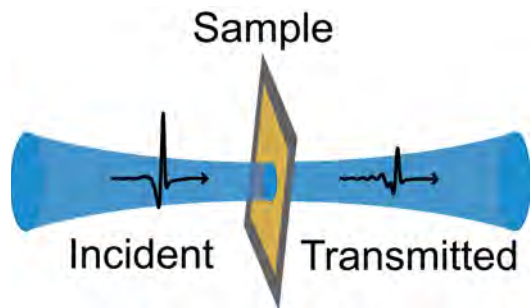
### THz-detection:



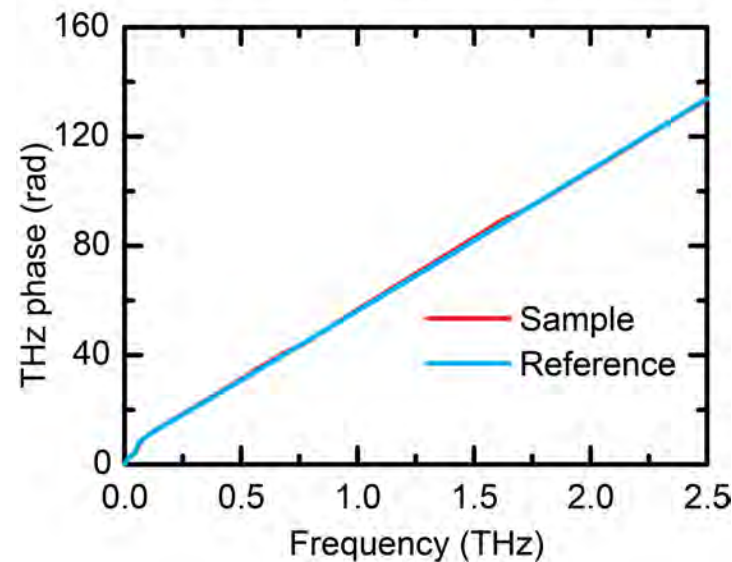
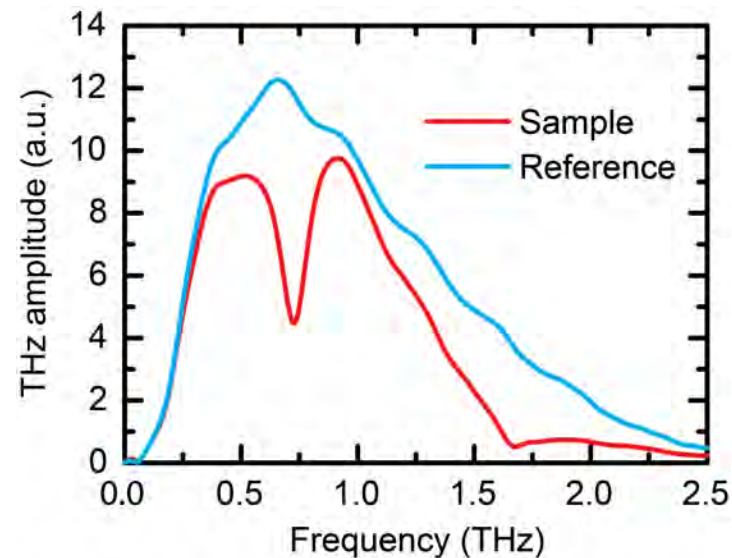
Measure the THz pulse waveform  
in the time-domain



# Terahertz Time-Domain Spectroscopy



FFT

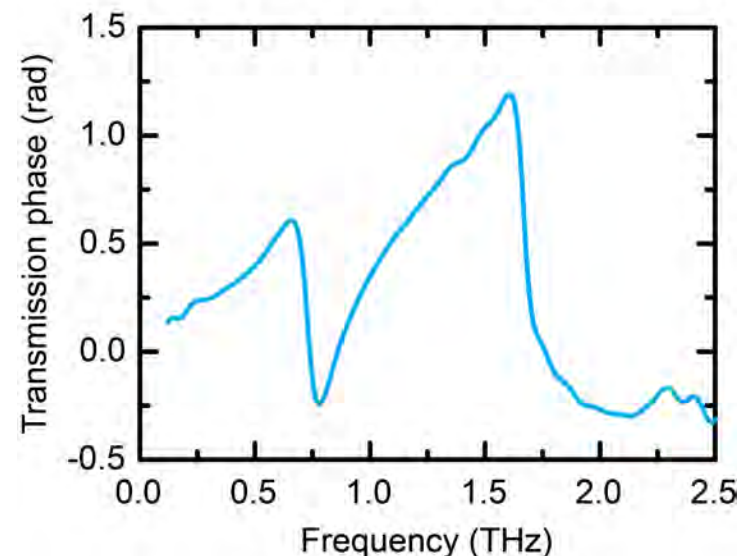
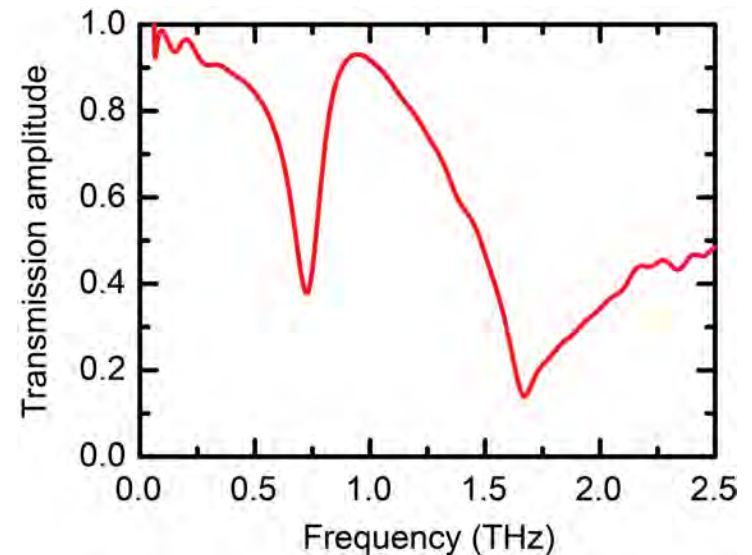




# Terahertz Time-Domain Spectroscopy

$$\tilde{t}(\omega) = \frac{E_{\text{Sam}}(\omega)}{E_{\text{Ref}}(\omega)}$$

- ❑ Obtain simultaneously the amplitude and phase information
- ❑ To extract complex dielectric function  $\epsilon(\omega)$  over a broad frequency range (non-magnetic materials)
- ❑ Reflection measurement is also required to further extract the complex permeability  $\mu(\omega)$  for materials with magnetic response



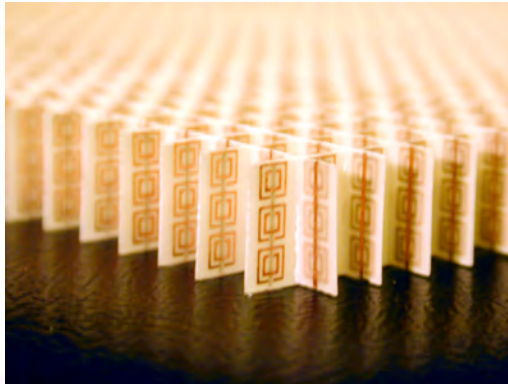
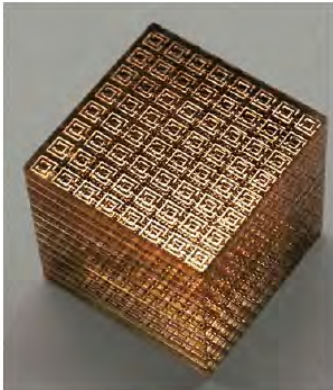




# Bulk Metamaterials vs Meta-Surfaces

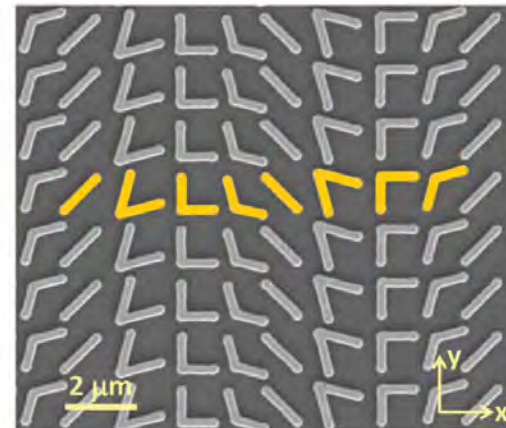
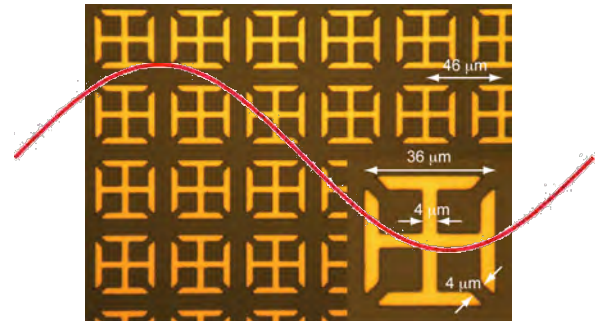
## Bulk metamaterials

- ❑ Effective material parameters:  $\epsilon$ ,  $\mu$ ,  $n$ ,  $Z$
- ❑ Difficult to fabricate in the optical regime
- ❑ High loss and narrow bandwidth issues



## Meta-surfaces

- ❑ Interface properties
- ❑ Planar structures: ease in fabrication
- ❑ Limited interaction with EM waves



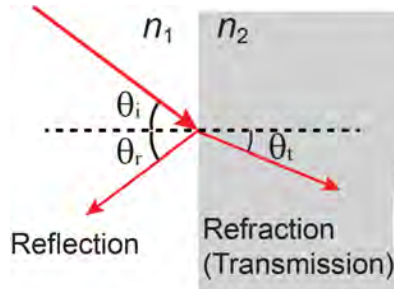


# Tailored Reflection and Transmission at Meta-Surfaces

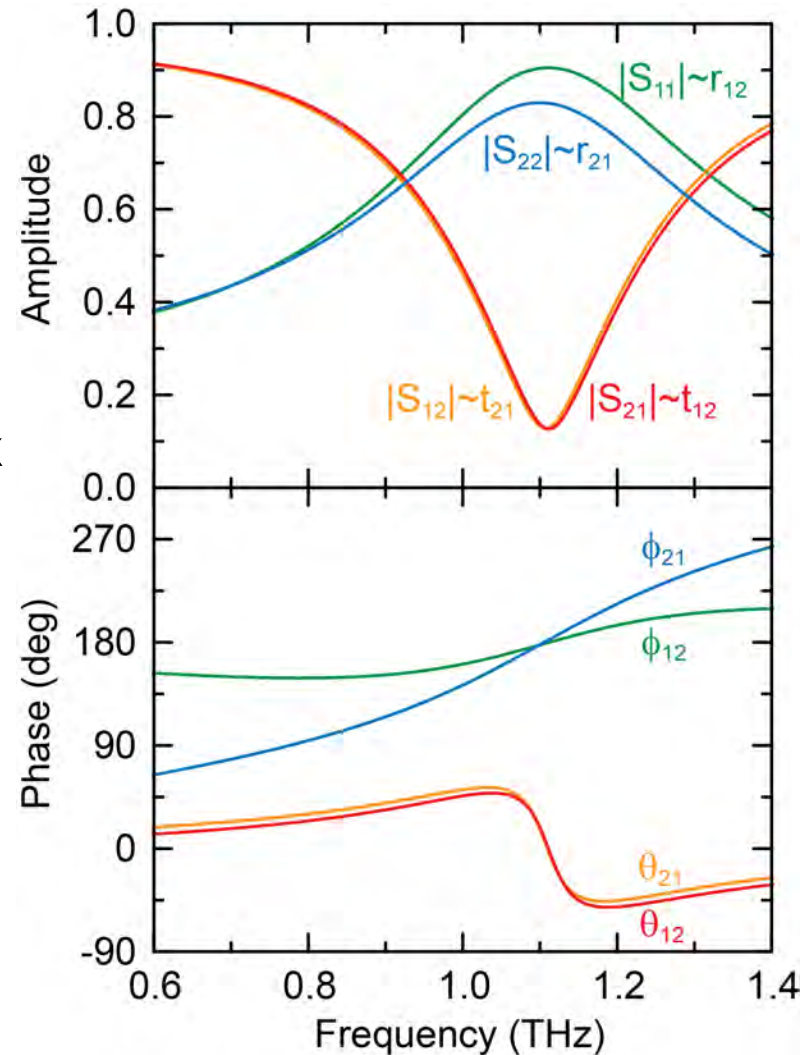
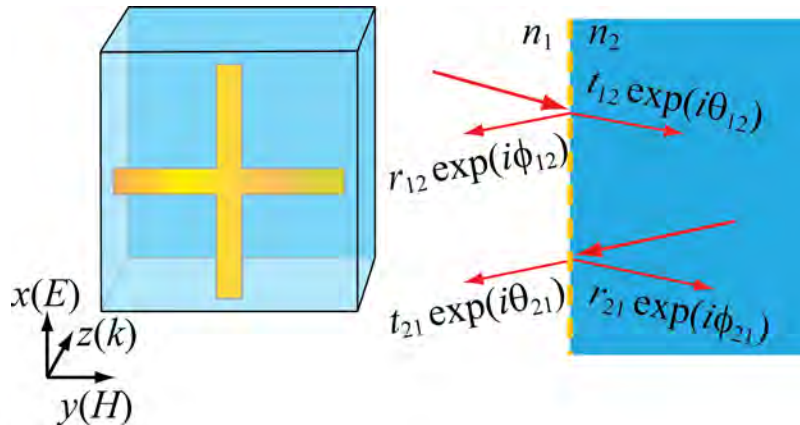
- For a bare dielectric surface:

$$r = \frac{n_1 - n_2}{n_1 + n_2} \quad t = \frac{2n_1}{n_1 + n_2}$$

at normal incidence  
with constant values

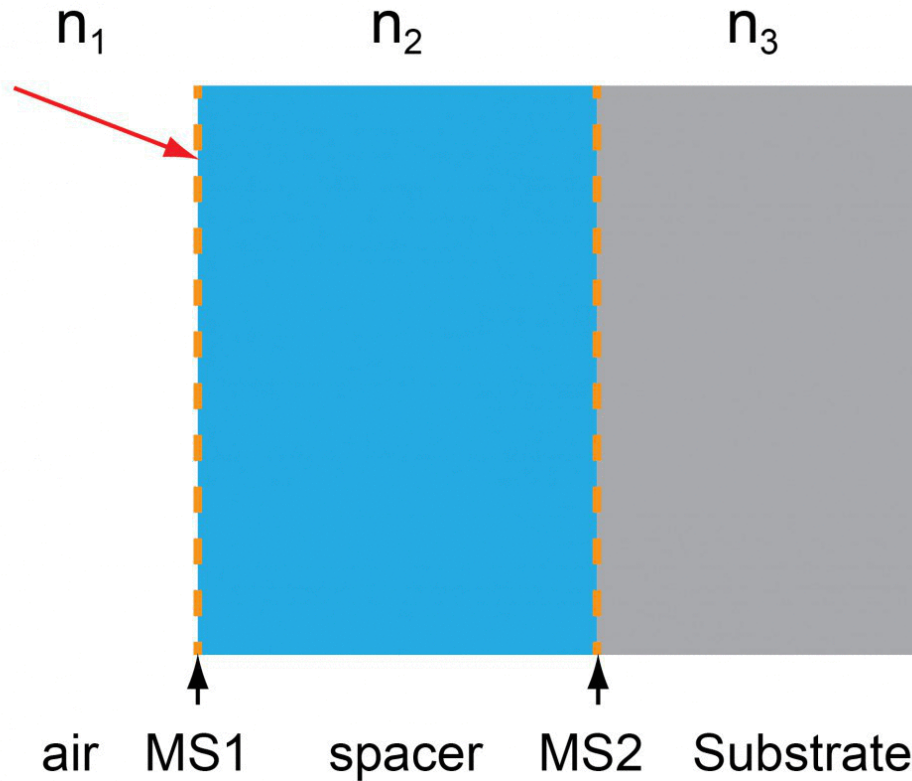


- The resonator array modifies the complex reflection and transmission coefficients with **strong dispersion** at the interface





# Interference in Few-Layer Metamaterials

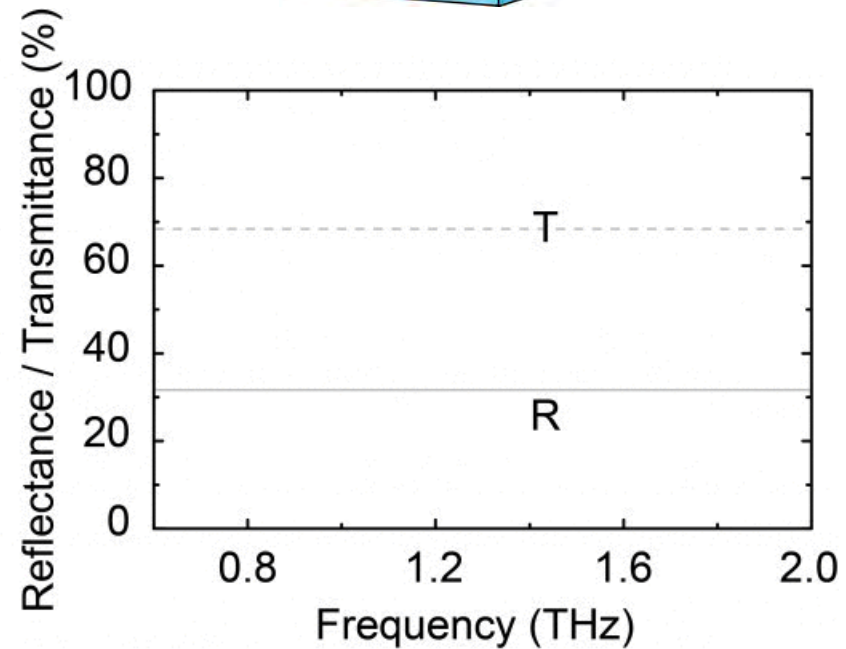
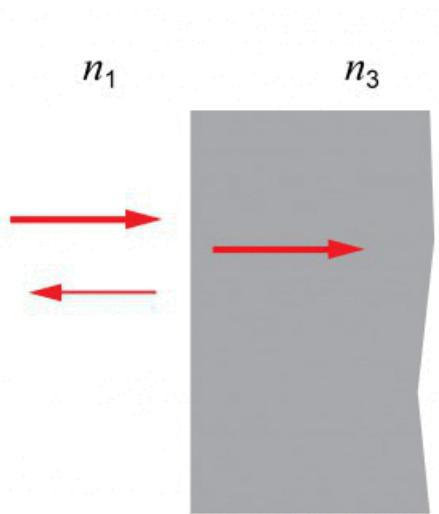
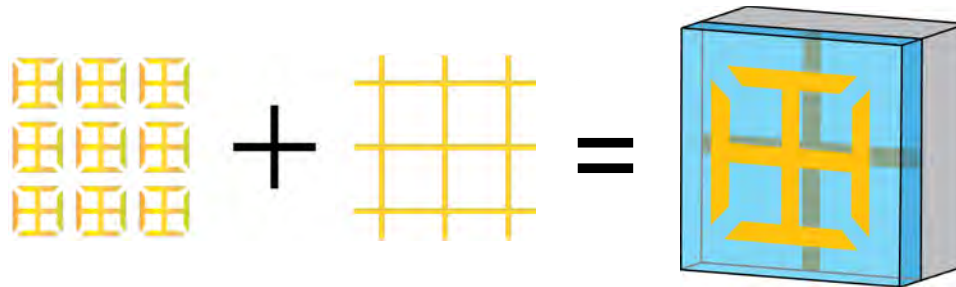


$$\tilde{r} = \tilde{r}_{12} + \frac{\tilde{t}_{12}\tilde{t}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$

$$\tilde{t} = \frac{\tilde{t}_{12}\tilde{t}_{23}e^{i\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$



# Ultrathin Bi-Layer Metasurface Antireflection Coatings

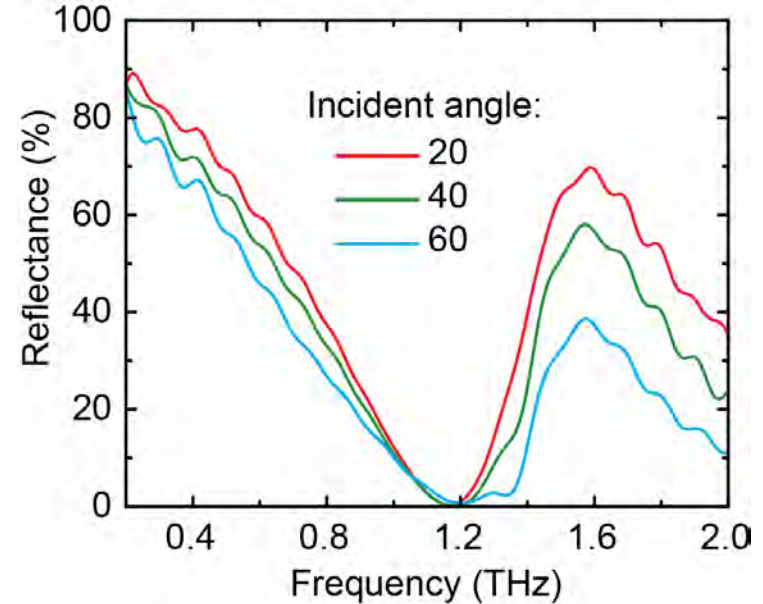
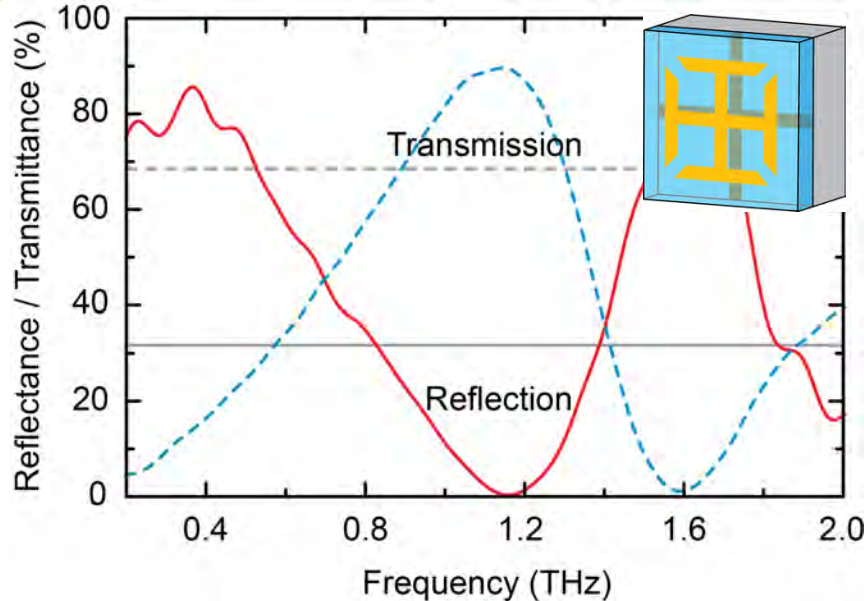


$$n_1 = 1, n_2 = 1.2, n_3 = 3.4$$





# Ultrathin Bi-Layer Metasurface ARC: Experiments



## Structure:

- Period ( $46\ \mu\text{m}$ ); gold width ( $4\ \mu\text{m}$ ); SRR outer dimension ( $36\ \mu\text{m}$ ); gold thickness ( $200\ \text{nm}$ ); gap ( $4\ \mu\text{m}$ )
- Polyimide spacer thickness ( $\sim 13\ \mu\text{m}$ ), dielectric constant ( $\sim 3$ ), loss tangent: ( $\sim 5\%$ )

## Performance:

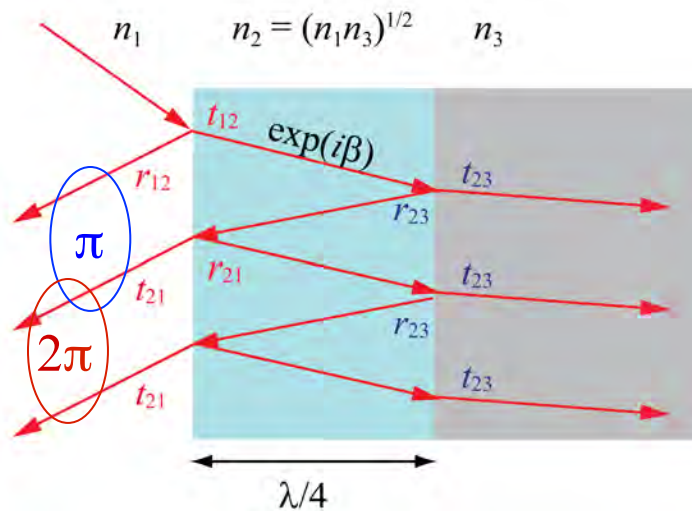
- Reflectance:  $32\% \rightarrow \sim 0$
- Transmittance:  $68\% \rightarrow 90\%$
- Wide incidence angle range
- No requirement of index matching

Chen *et al.*, *Phys. Rev. Lett.* **105**, 073901 (2010).



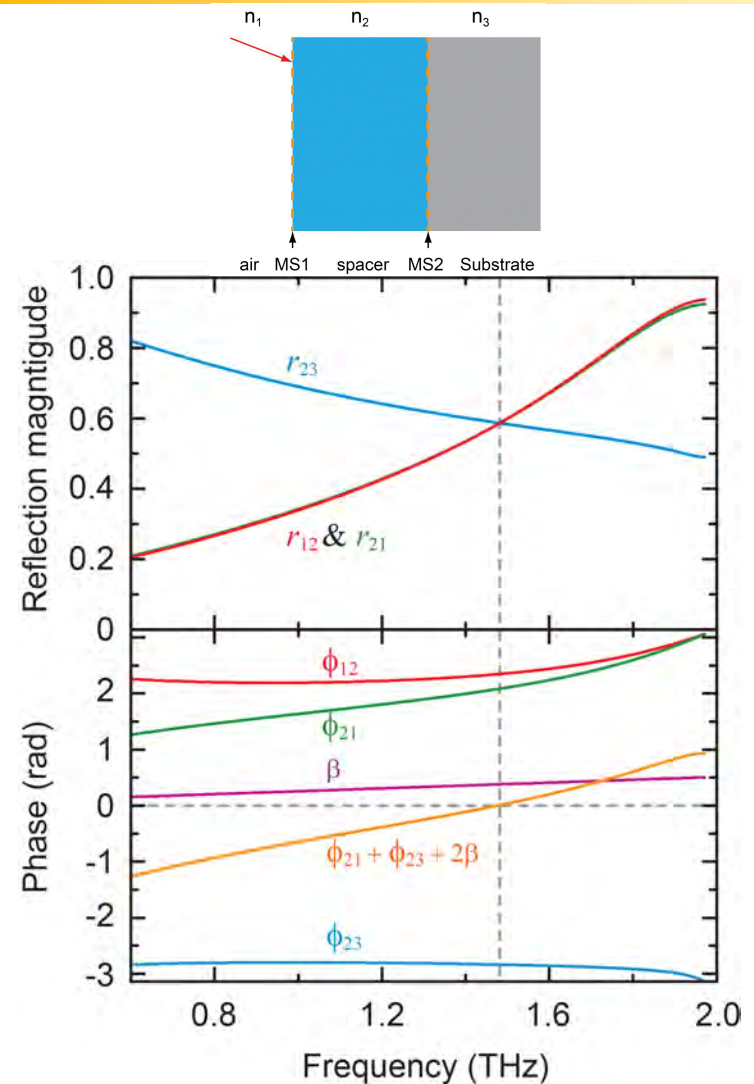
# Mechanism of Metamaterial Antireflection

## Quarter-wave antireflection:



## Metasurface antireflection:

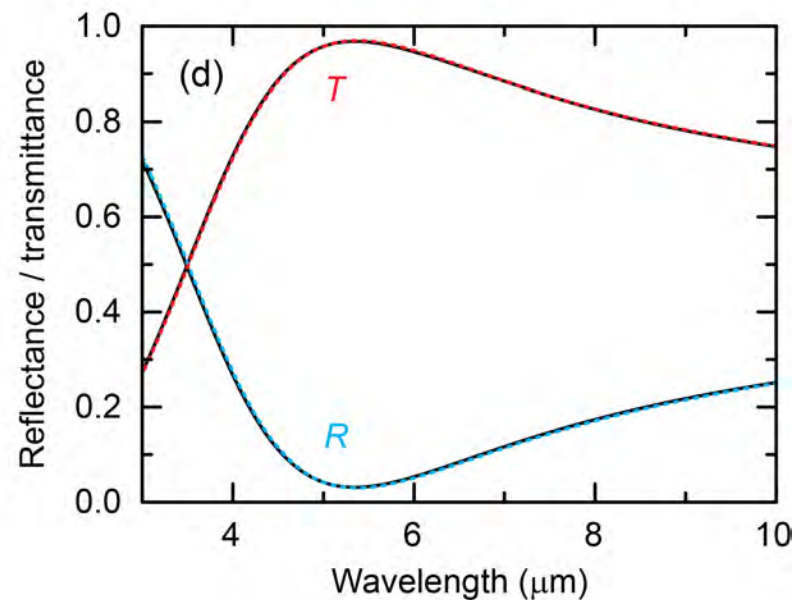
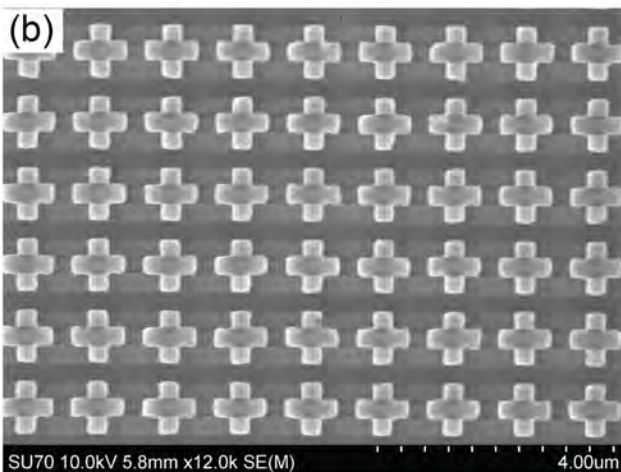
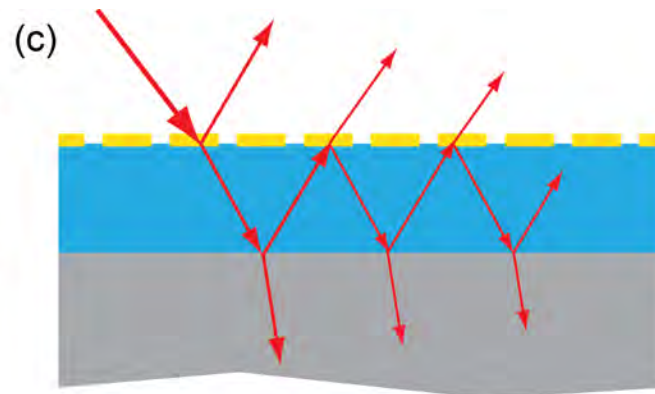
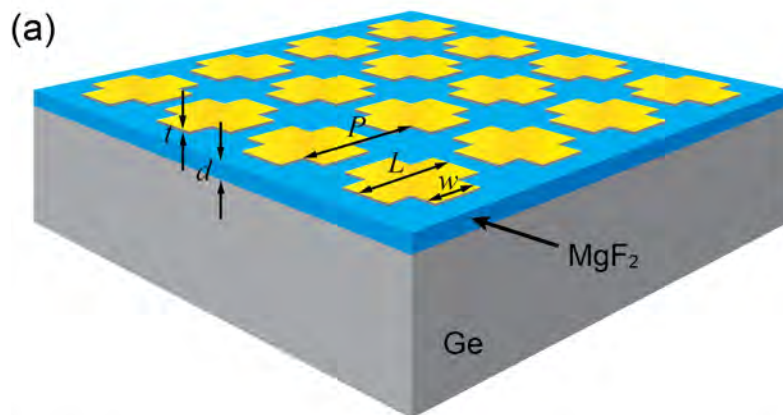
- $r_{12} = r_{21} = r_{23}$
- $\theta_{12} + \phi_{23} + \theta_{21} + 2\beta - \phi_{12} = \pi$
- $\phi_{21} + \phi_{23} + 2\beta = 0$



Chen et al., *Phys. Rev. Lett.* **105**, 073901 (2010).



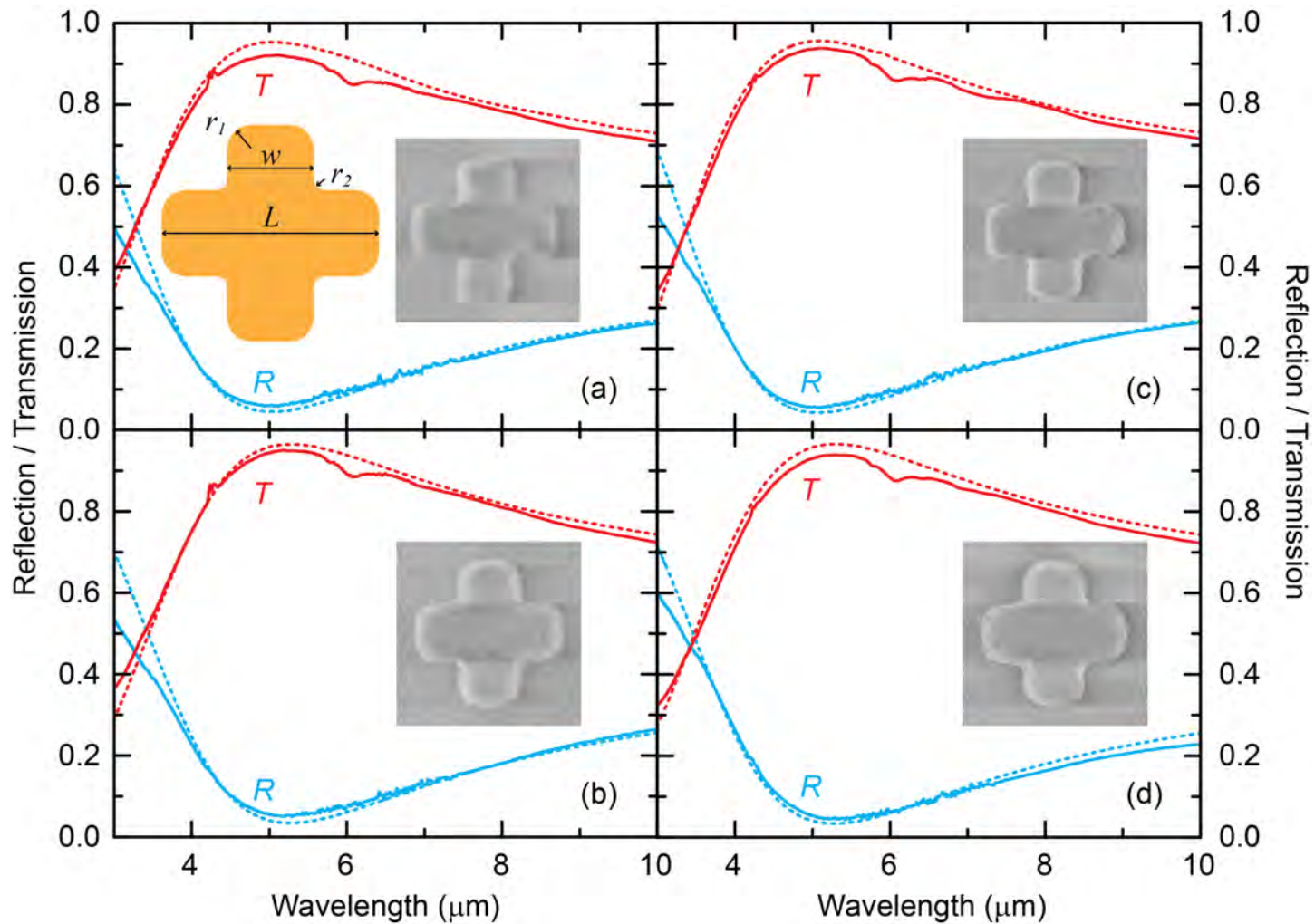
# Single-Layer Metasurface ARC in MIR







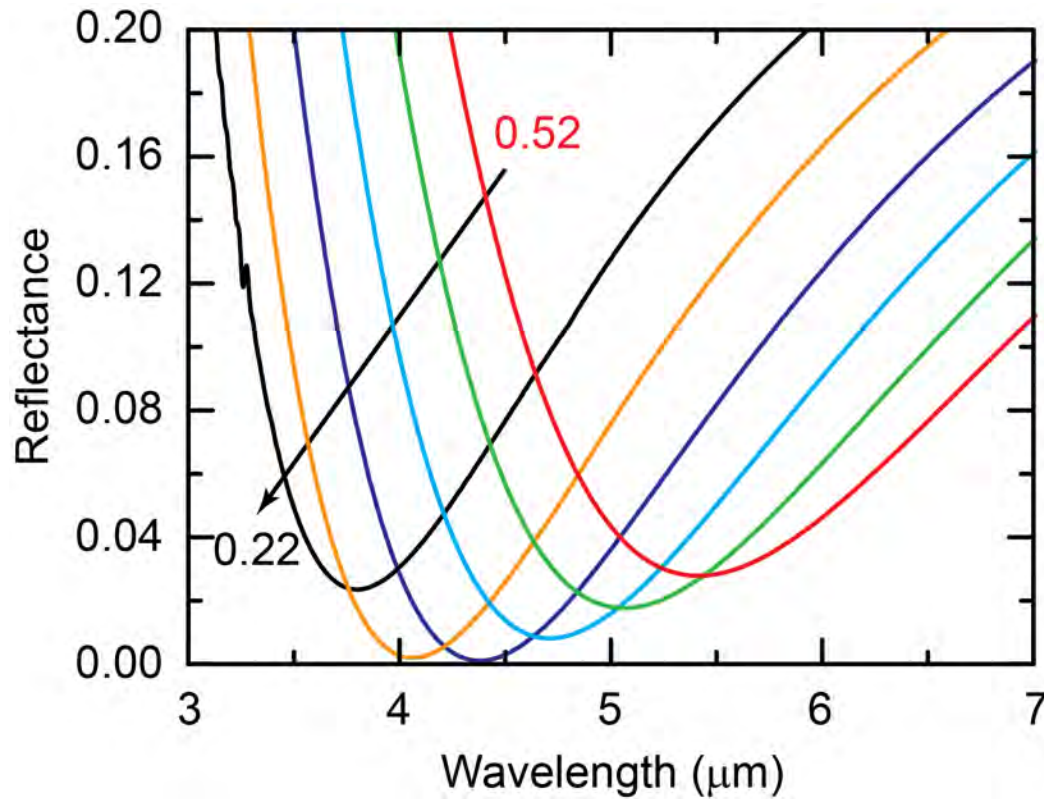
# Single-Layer Metasurface ARC in MIR







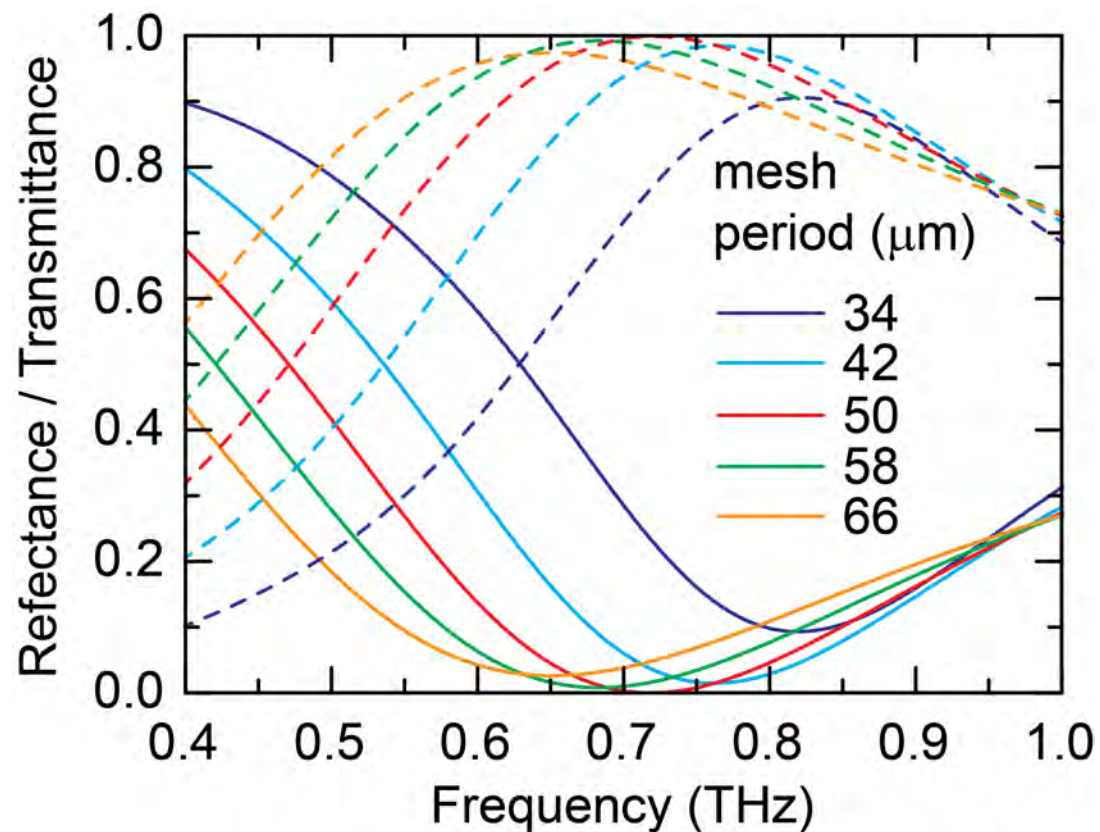
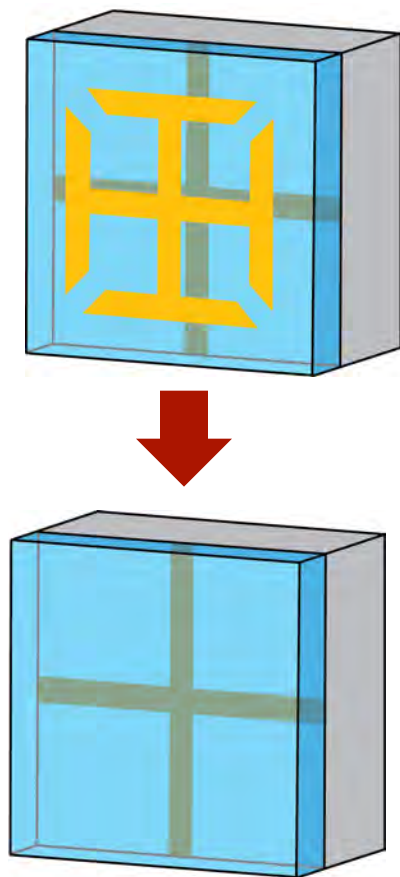
# Spacer Thickness Dependence



- ❑ The spacer thickness (520 nm) is too much in our experiments
- ❑ The optimized spacer thickness is ~320 nm



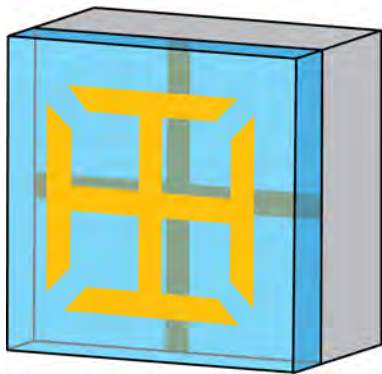
# Laminating Silicon on Metal Mesh as ARC



- Define metal mesh on top of the silicon substrate
- Laminate thin silicon superstrate (~20  $\mu\text{m}$  thick)

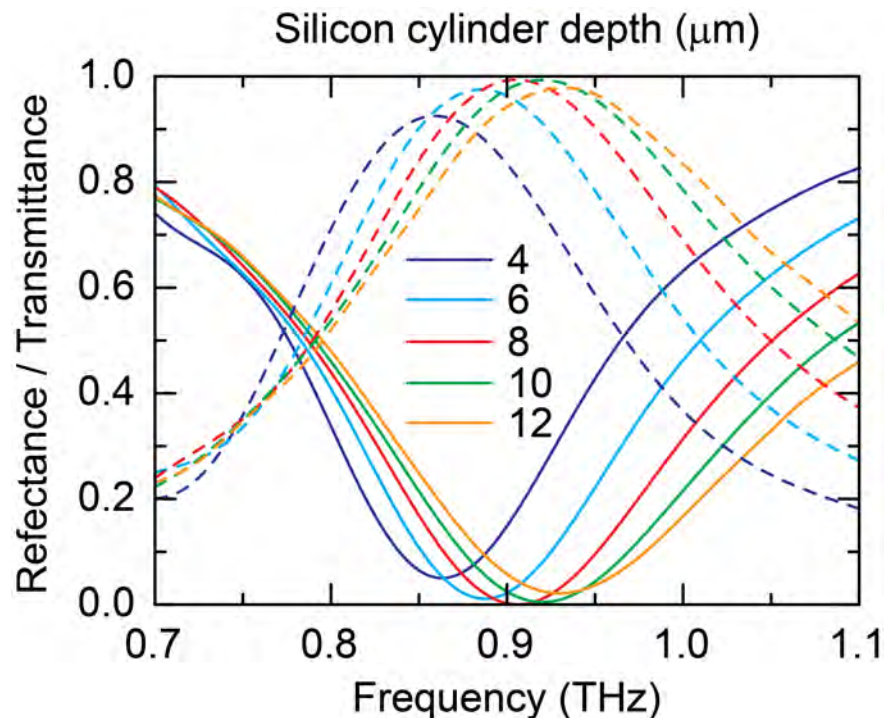


# Metal-Coated Silicon Pillar Array for ARC



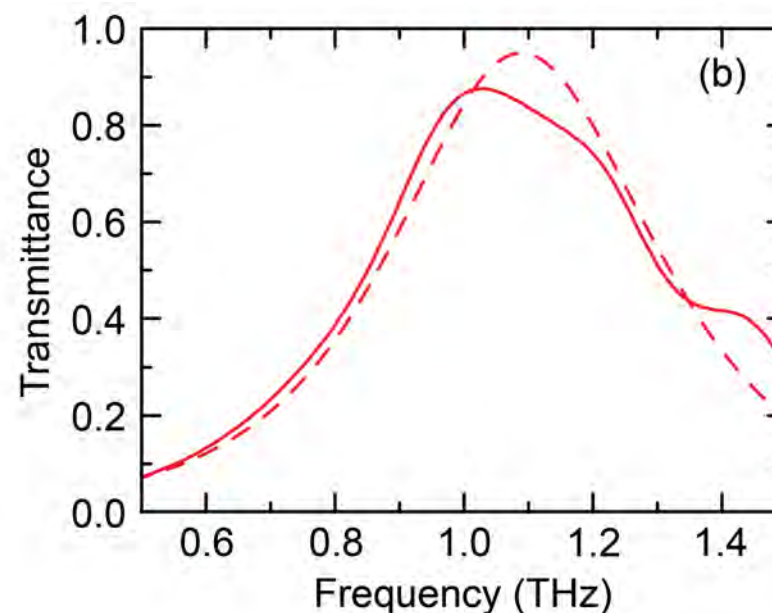
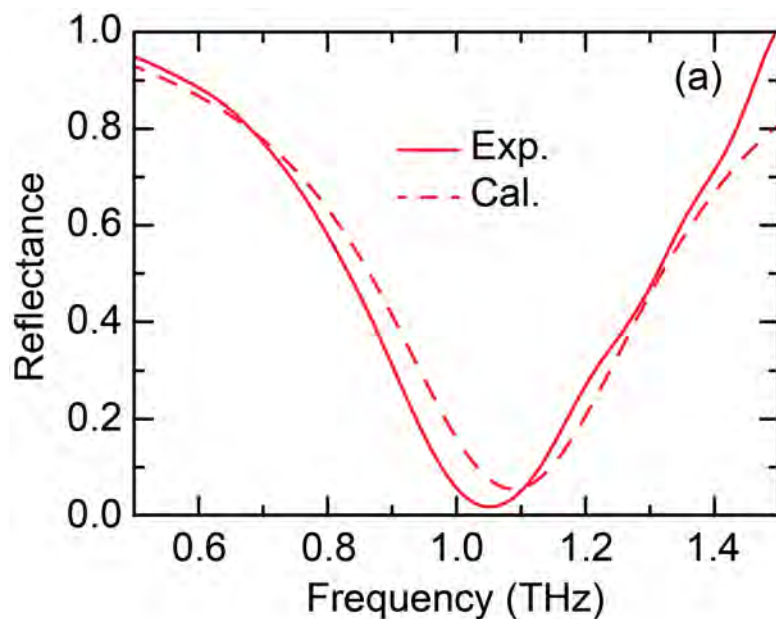
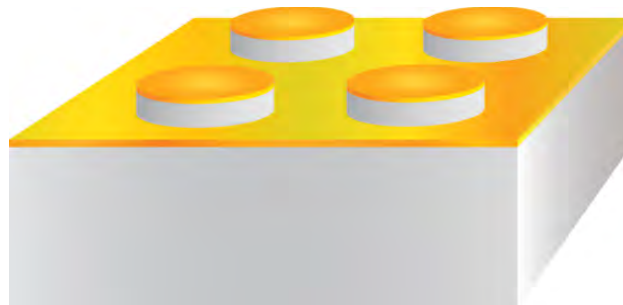
## ❑ Fabrication:

- Photolithography to define the cylinders (diameter~50  $\mu\text{m}$ , period~60  $\mu\text{m}$ )
- RIE to form the silicon cylinders (~8  $\mu\text{m}$  depth)
- (Directional) metal deposition (200 nm gold)





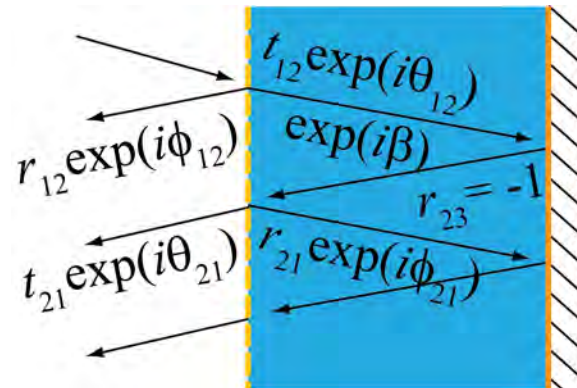
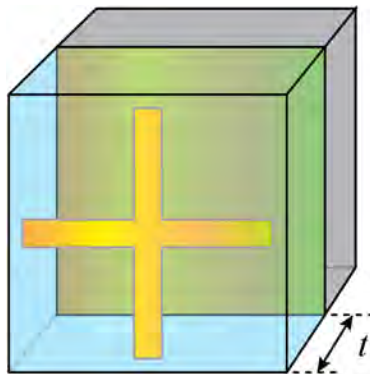
# Metal-Coated Silicon Pillar Array for ARC



□ Additional sample fabrication and measurements are going on

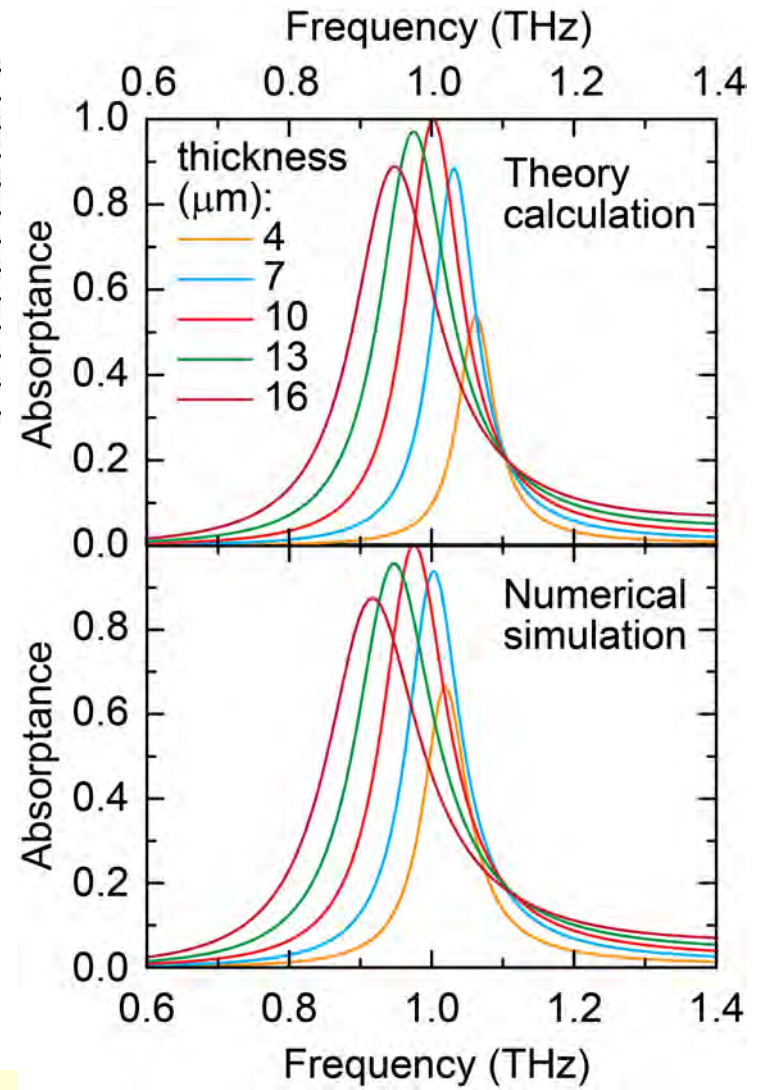


# Metamaterial Perfect Absorbers: Trapped Light



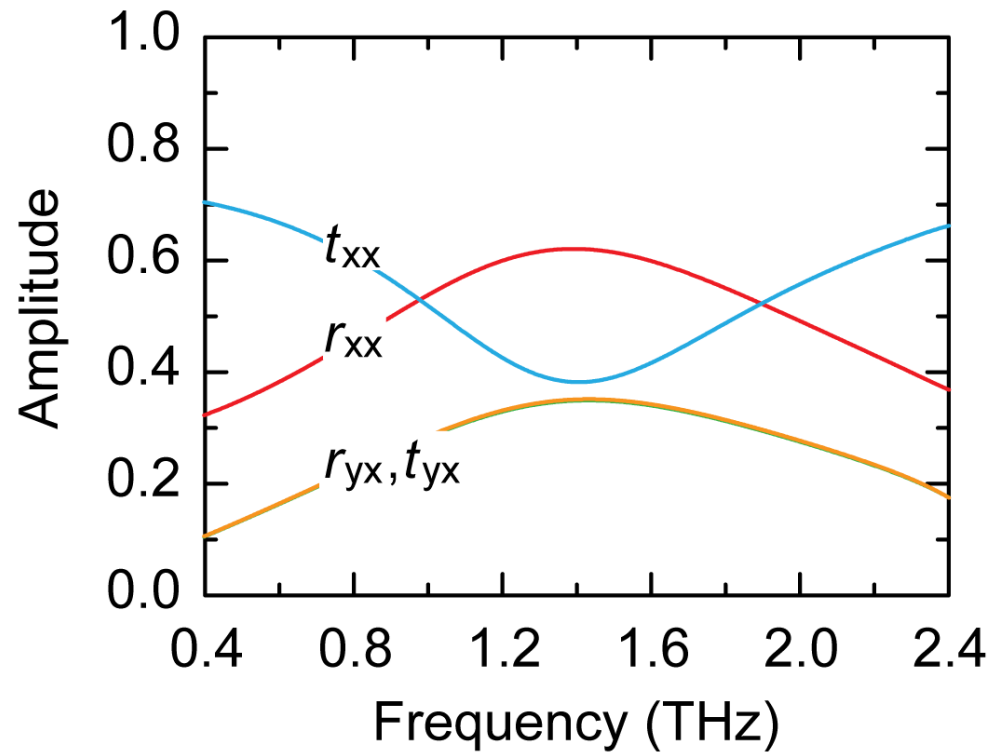
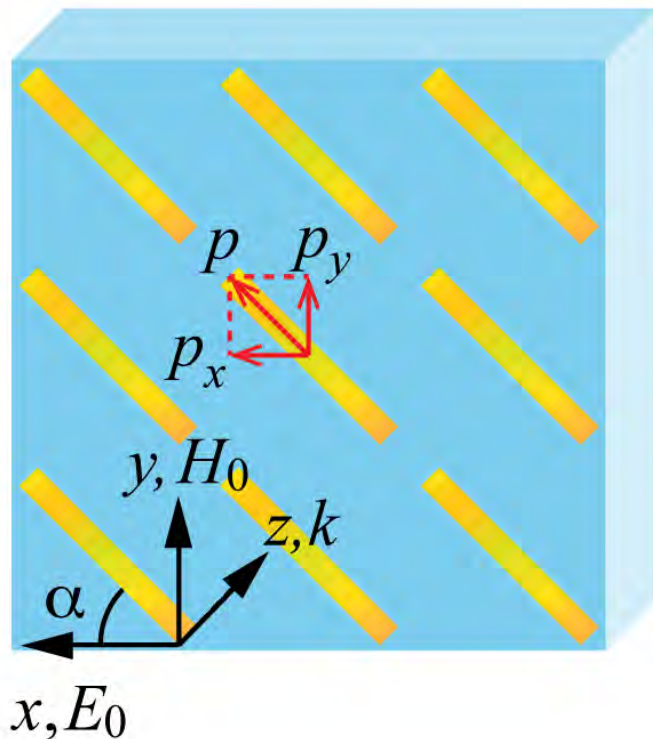
$$\tilde{r} = \tilde{r}_{12} + \frac{\tilde{t}_{12}\tilde{t}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$

- ❑ Zero transmission due to the metal ground plane
- ❑ Minimizing reflection due to destructive interference of multi-reflection
- ❑ Absorptance:  $A = 1 - R$





# Anisotropic Metasurfaces

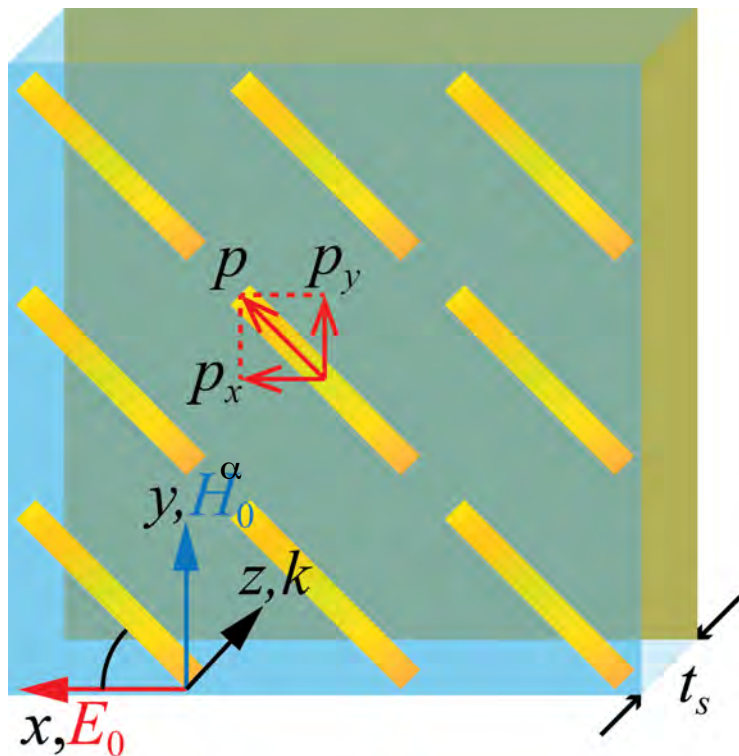


- ❑ Incident field  $\mathbf{E}_0$  along x-direction ( $\alpha=45^\circ$ ): the excited dipole  $\mathbf{p}$  has x- and y-components
- ❑ Single-layer metasurface:: Output waves are elliptically polarized

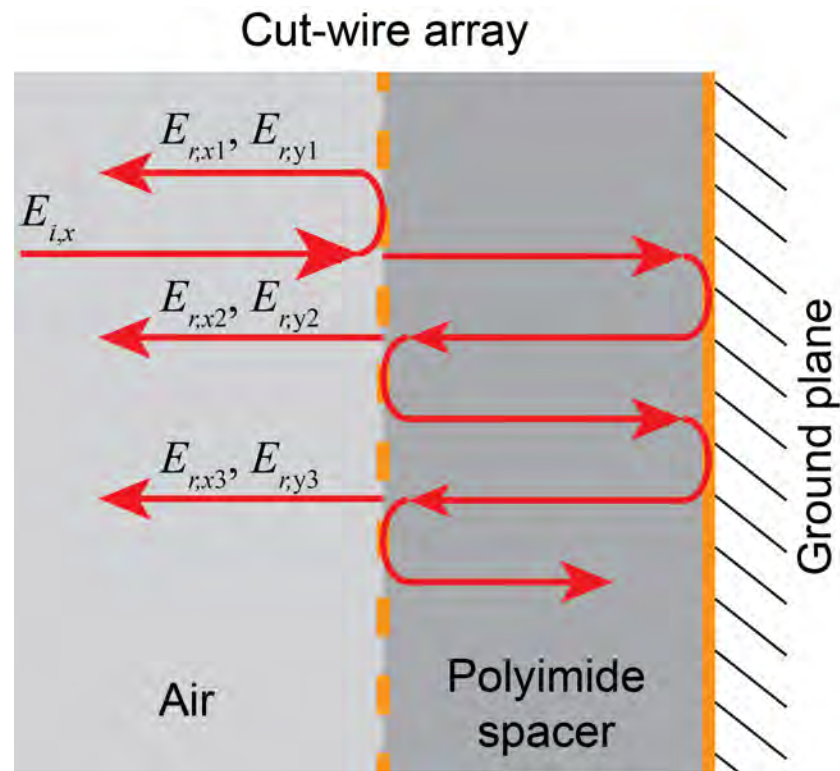


# Reflective Linear Polarization Converter

## Structure schematics



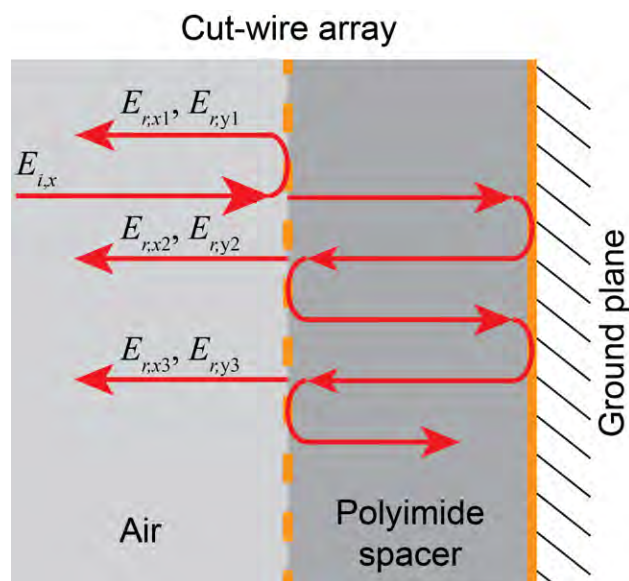
## Multireflection and conversion



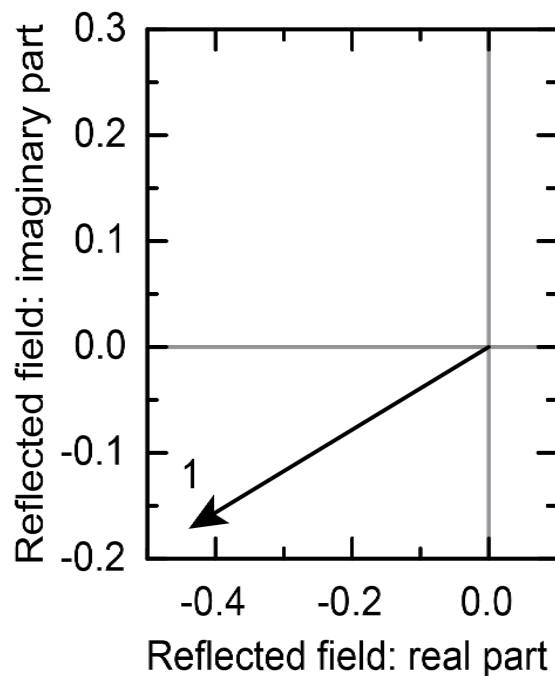


# Reflective Linear Polarization Converter

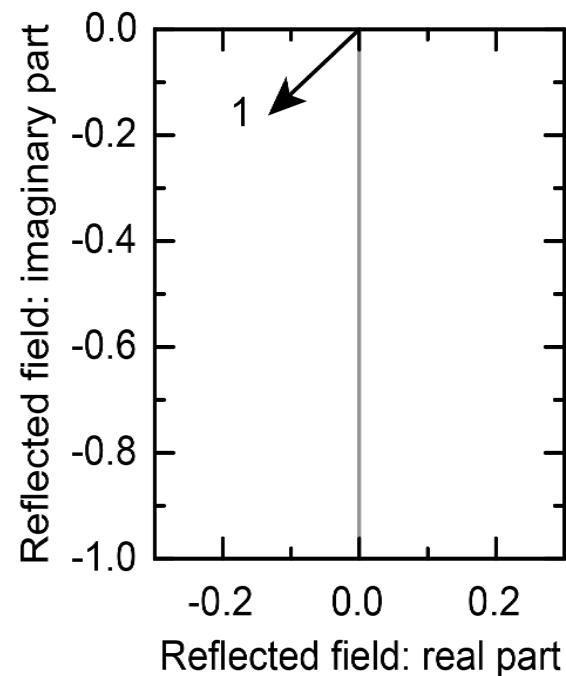
## Constructive and destructive interferences



co-polarized



cross-polarized

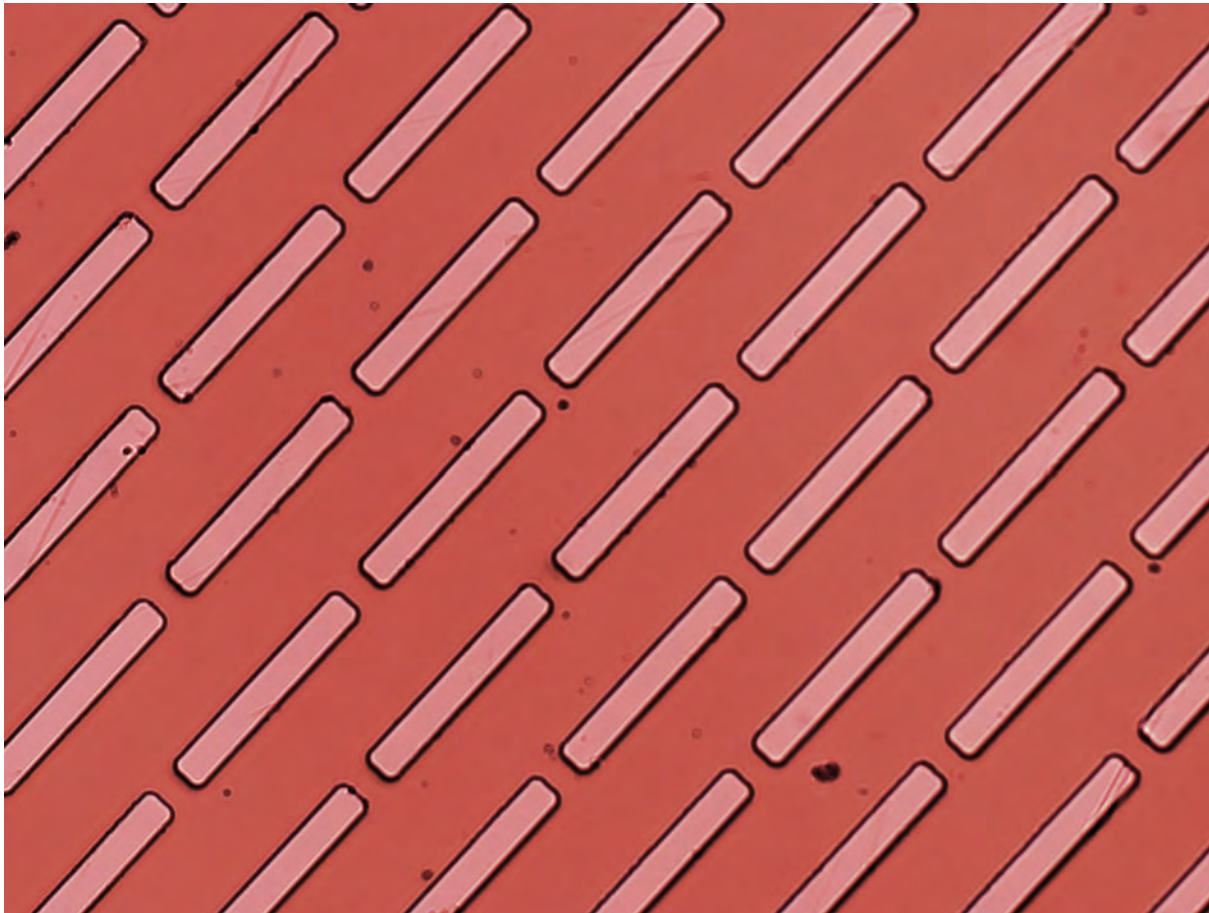






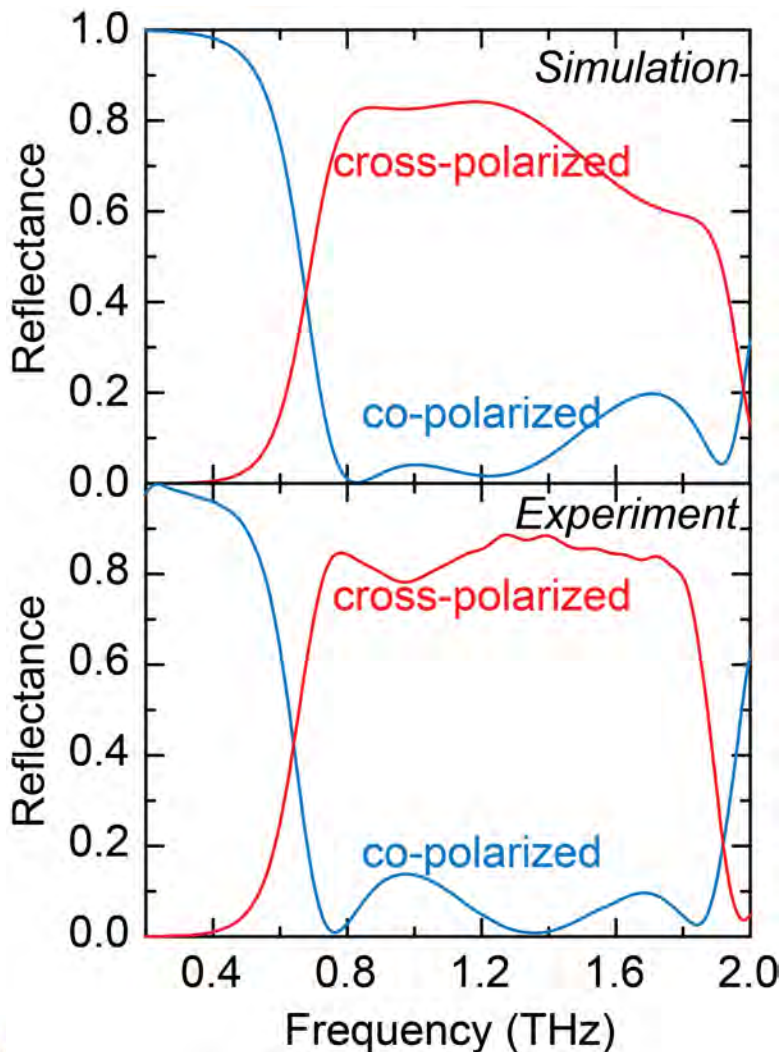
# Reflective Linear Polarization Converter

## Optical microscopy image





# Reflective Linear Polarization Converter



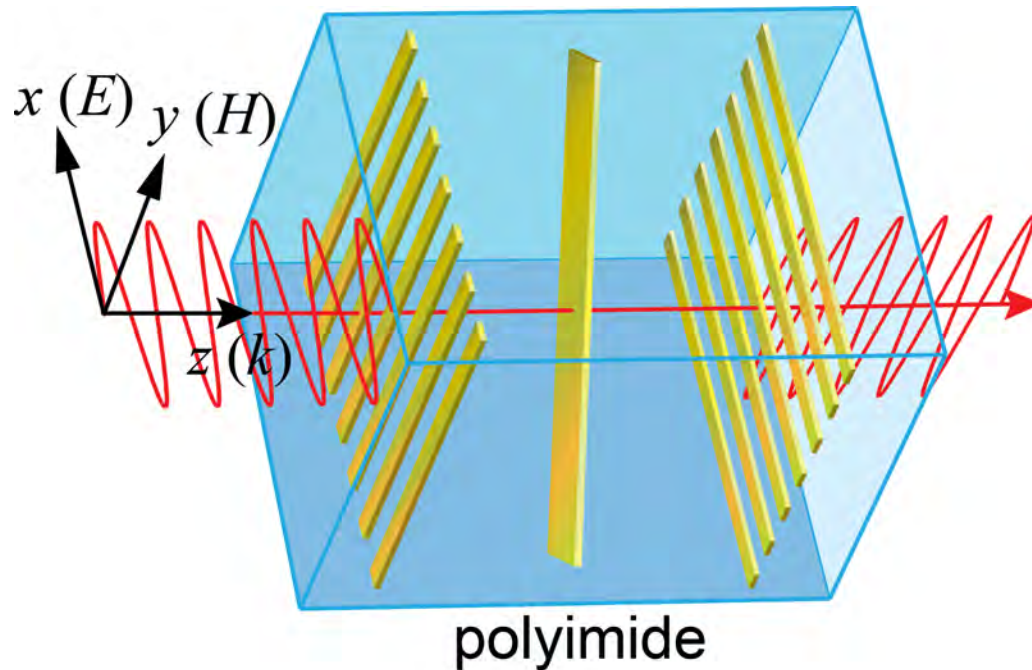
## Simulations and experiments

- ❑ Device thickness  $33\ \mu\text{m}$
- ❑ Operation center wavelength  $230\ \mu\text{m}$
- ❑ Co-polarized reflection is minimal
- ❑ Cross-polarized reflectance is more than 80%
- ❑ Broadband: destructive interference at multiple frequencies

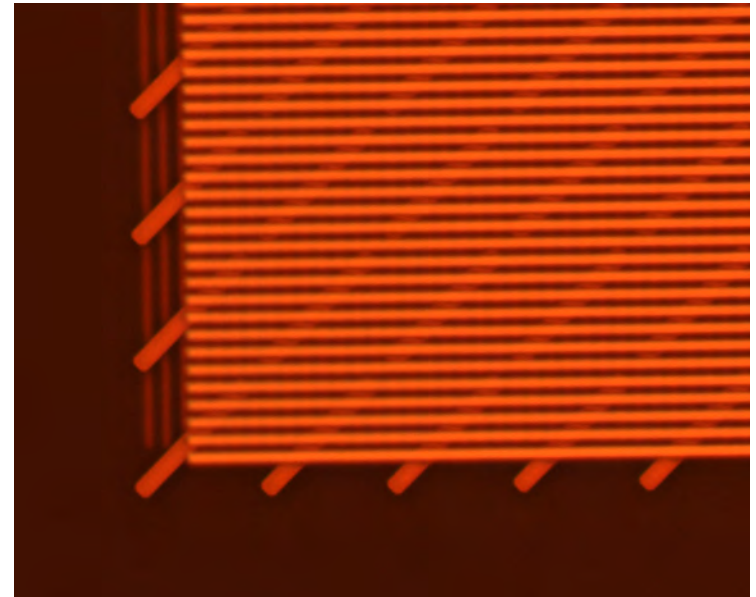


# Transmission Linear Polarization Converter

Structure schematic



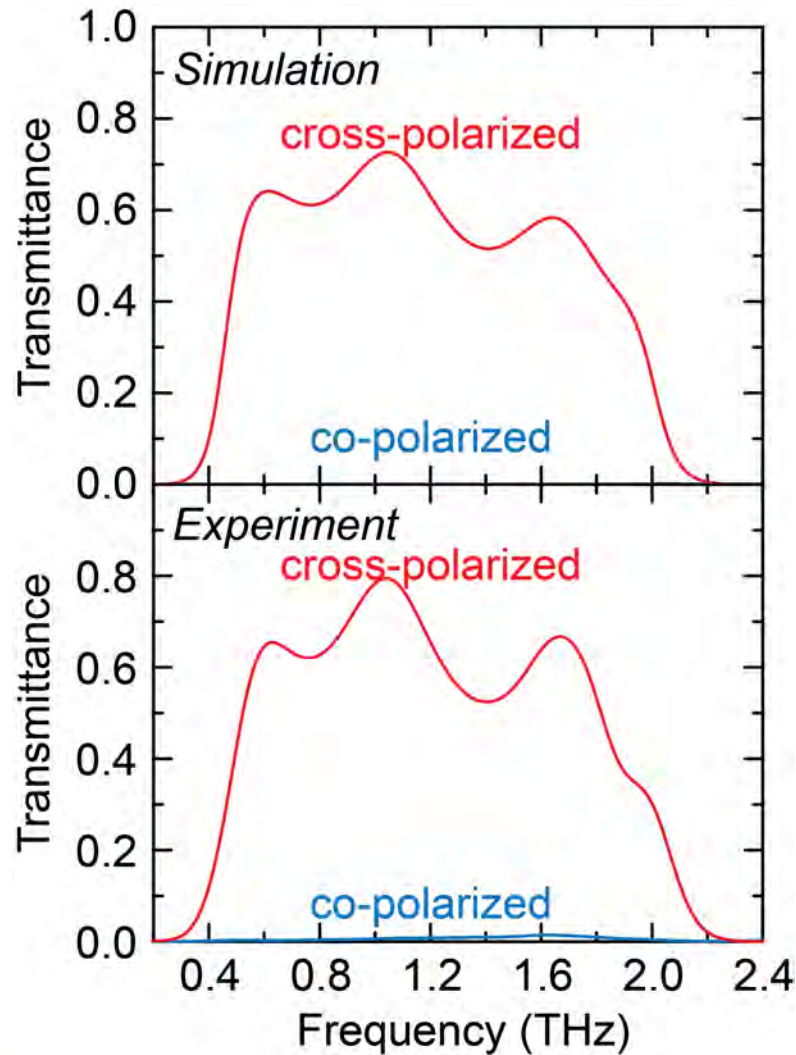
Optical microscopy image



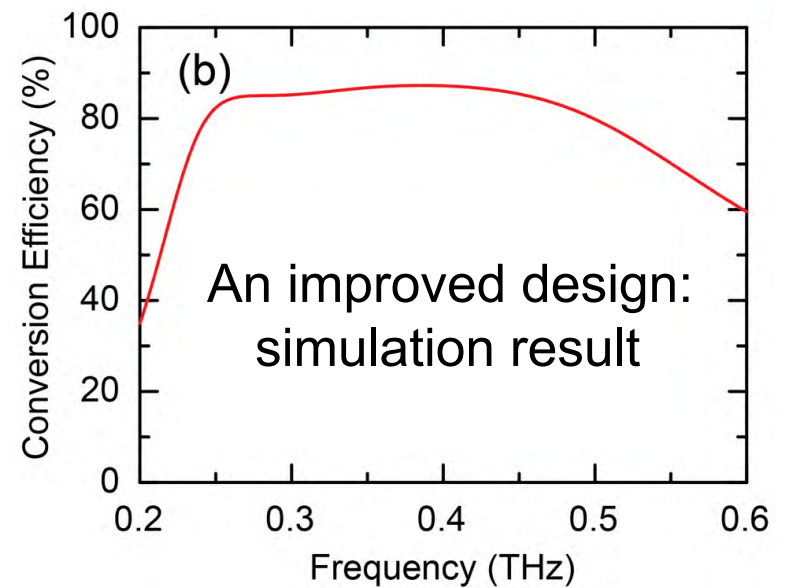
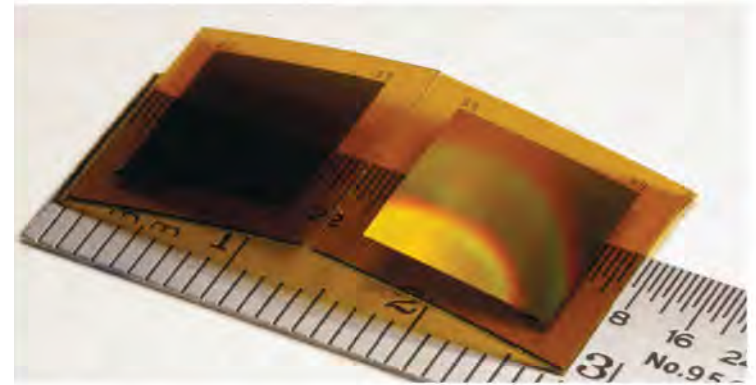




# Transmission Linear Polarization Converter



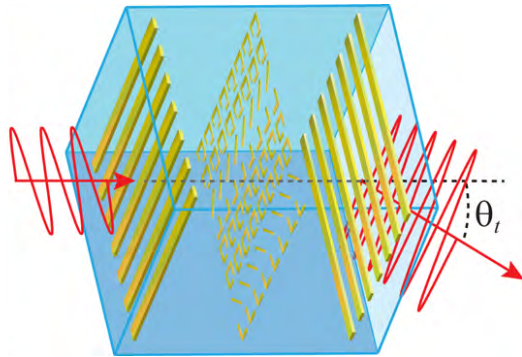
Fabricated thin film device



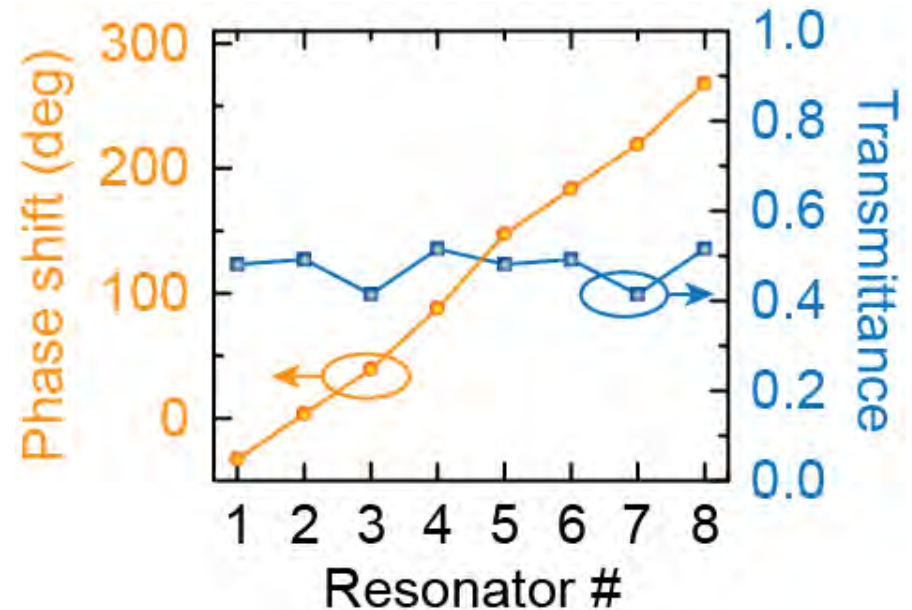




# Anomalous Refraction: Generalized Snell's Law



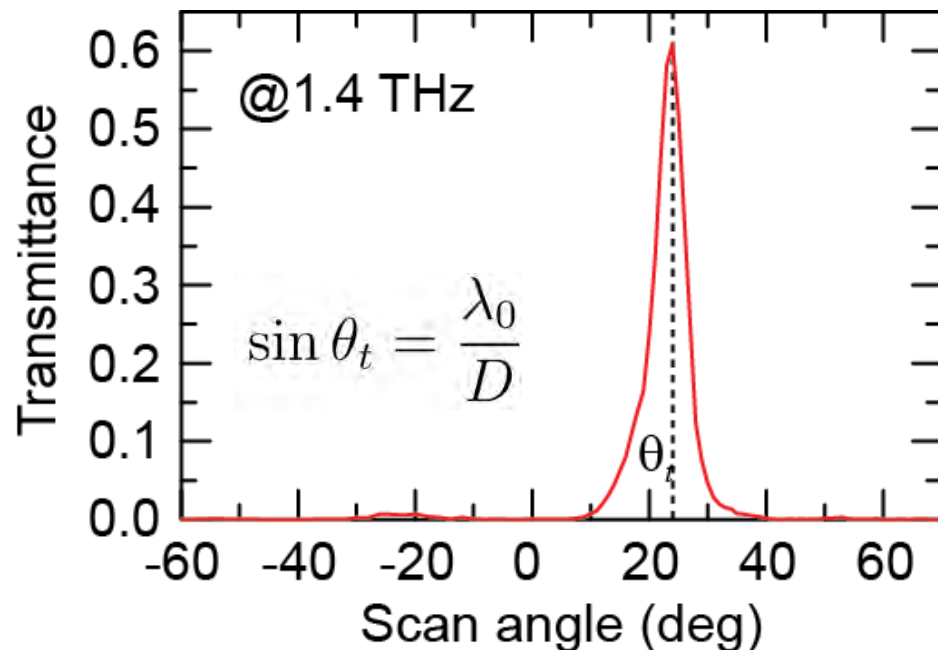
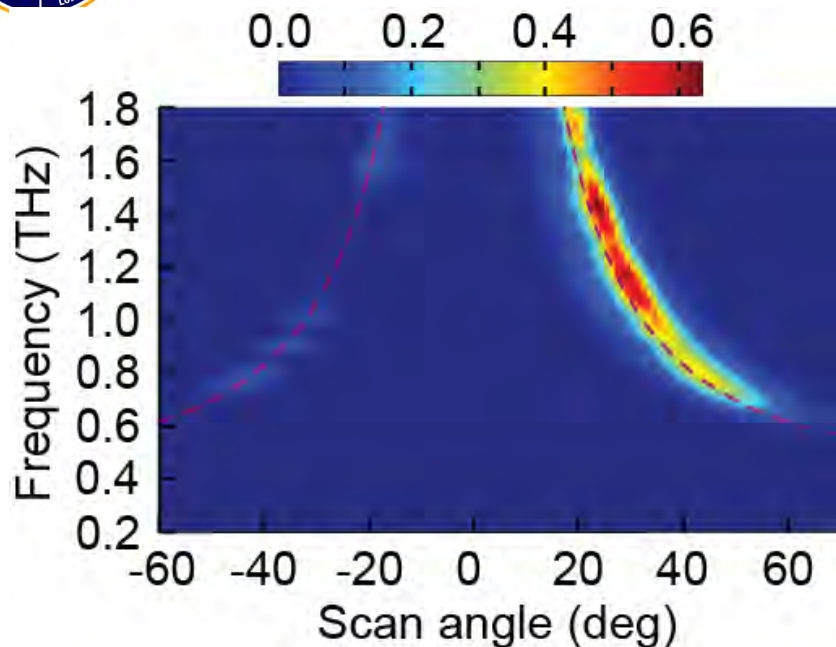
$$\sin \theta_t - \sin \theta_i = \frac{\lambda_0}{2\pi} \frac{d\Phi}{dx}$$



- ❑ Each individual element can be used in polarization converter
- ❑ Conversion efficiency is designed to be largely constant
- ❑ 8 elements form the unit cell, with a linear phase shift spanning a  $2\pi$  range



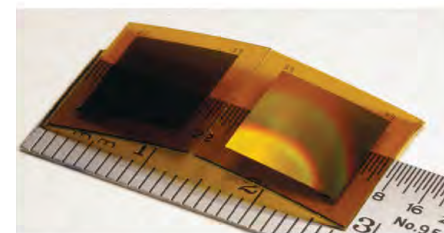
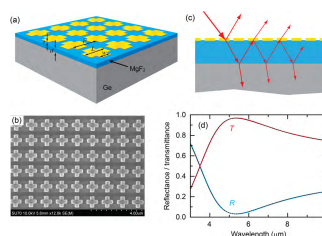
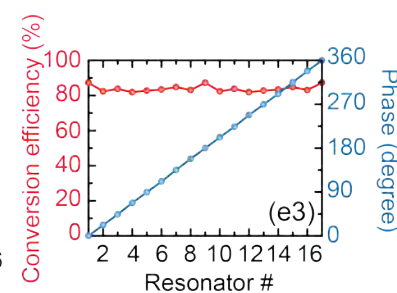
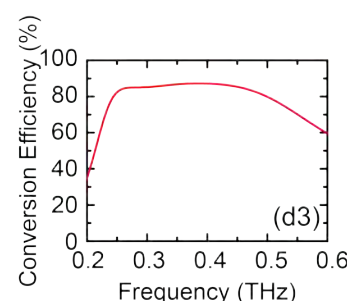
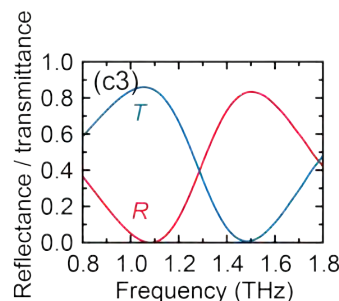
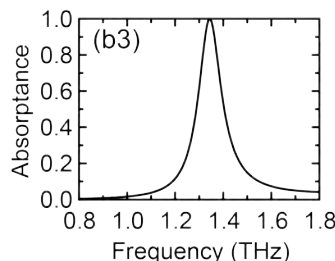
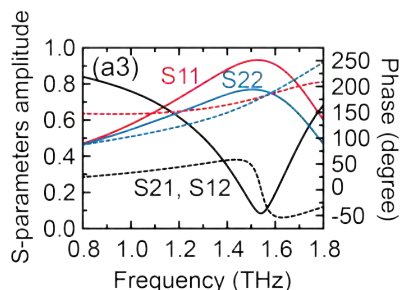
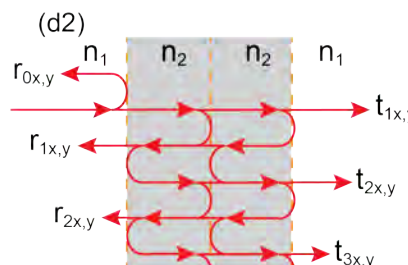
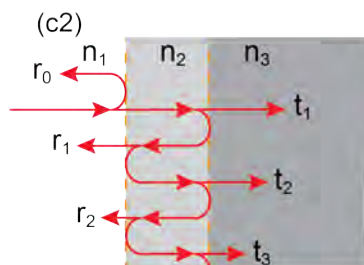
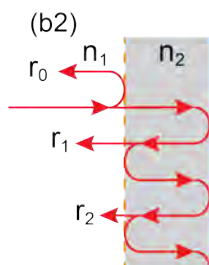
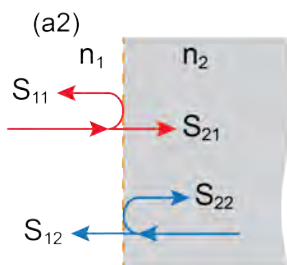
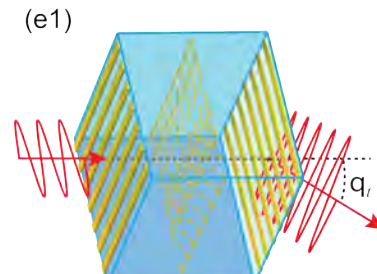
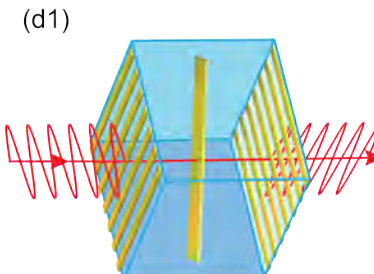
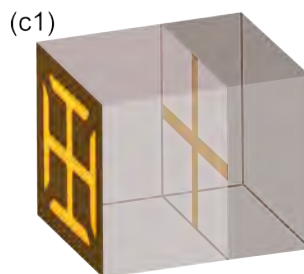
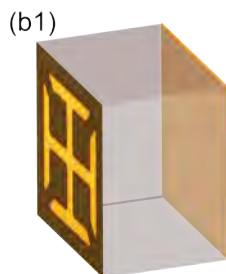
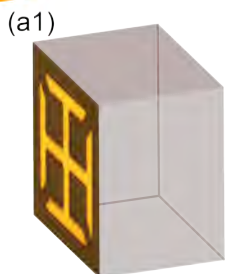
# Near-Perfect Anomalous Refraction: Exp.



- ❑ At a specific frequency, the “refraction angle” is determined by periodicity
- ❑ At 1.4 THz, the anomalous refraction carries 60% of the incident power
- ❑ Measure the cross-polarized transmission vs. scanning angle
- ❑ Operate over a broad bandwidth



# Summary of Few-Layer Metamaterials (Metasurfaces)

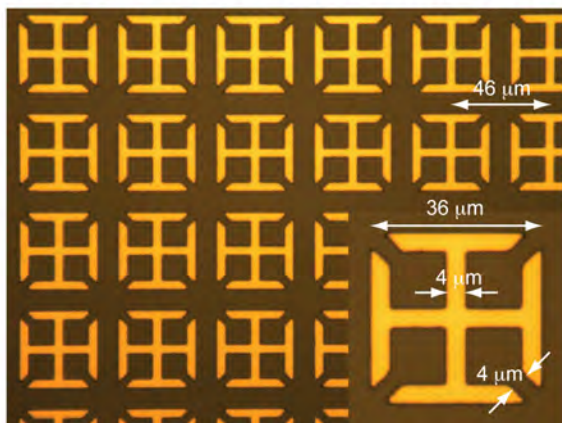




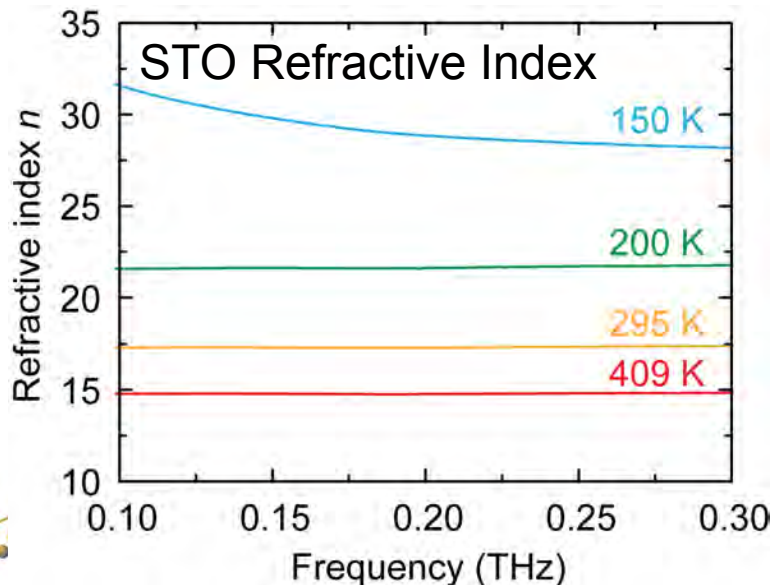


# Thermally Tunable Metasurface Resonance

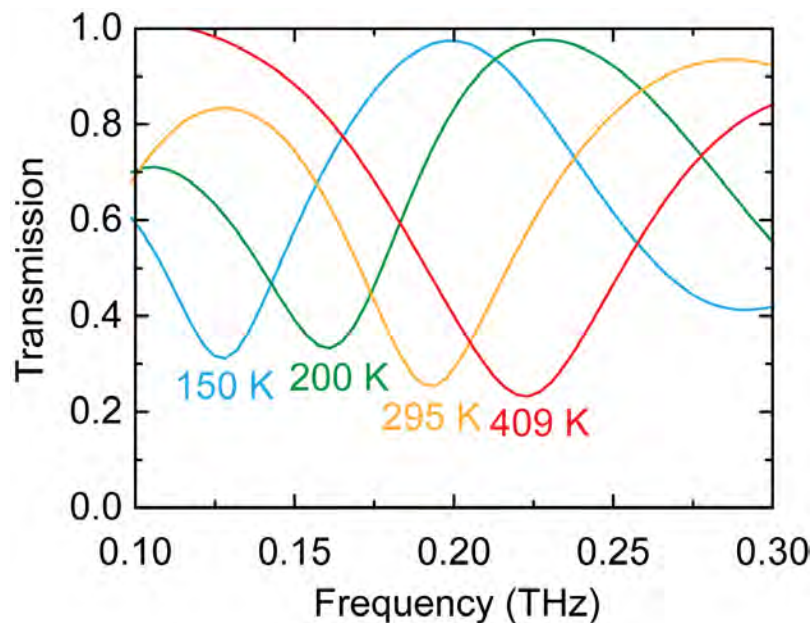
Strontium Titanate Substrate



$$\omega_0 = 1/\sqrt{LC} \sim 1/n$$



- ❑ Fabrication: photolithography, e-beam metal deposition, and lift-off process
- ❑ Substrate: silicon, gallium arsenide, etc.
- ❑ Resonance frequency tuning using strontium titanate (STO) substrate



*Opt. Lett.* **36**, 1230 (2011).





# Optically Switchable THz Metamaterials

GaAs substrate

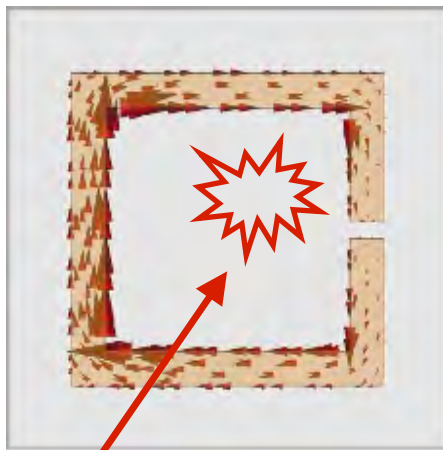
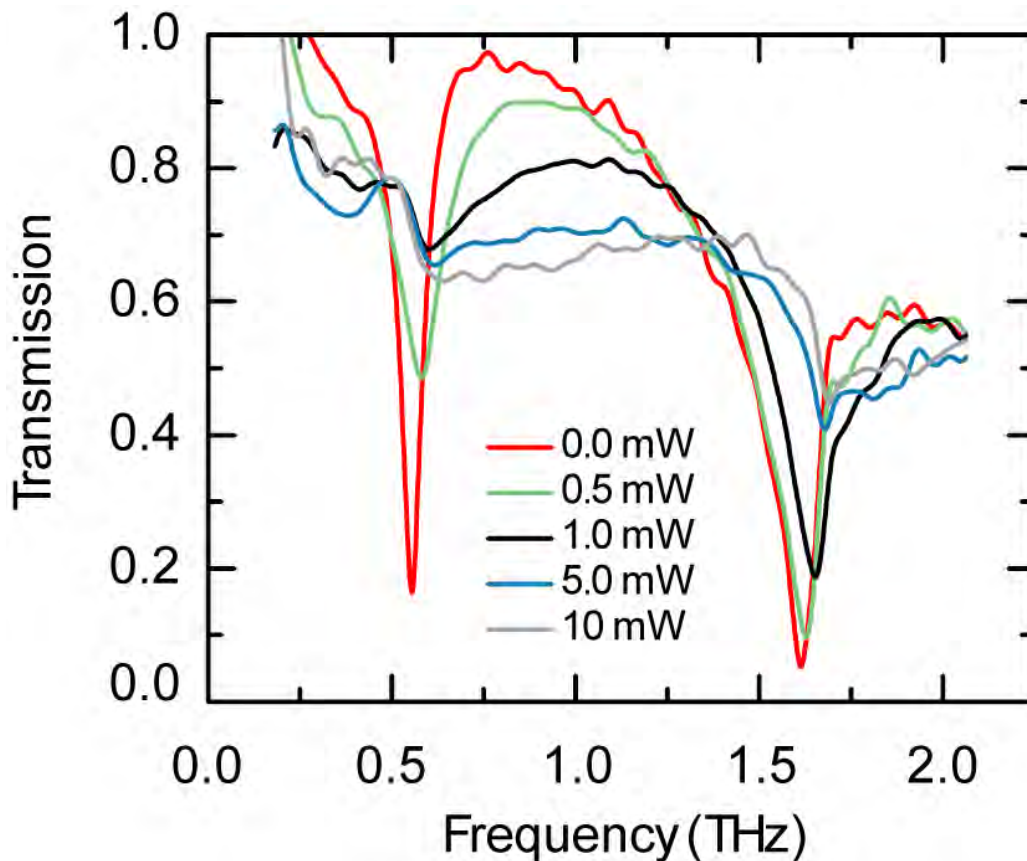
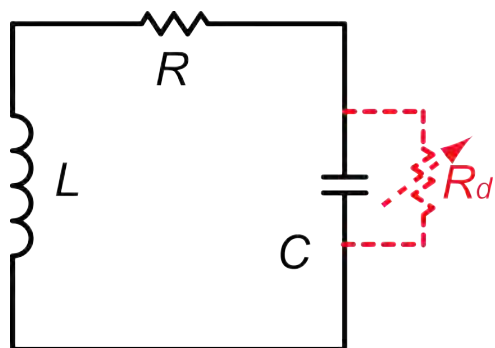
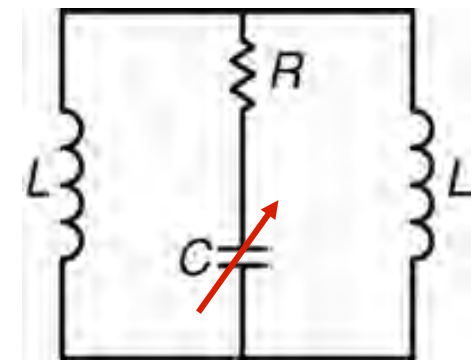
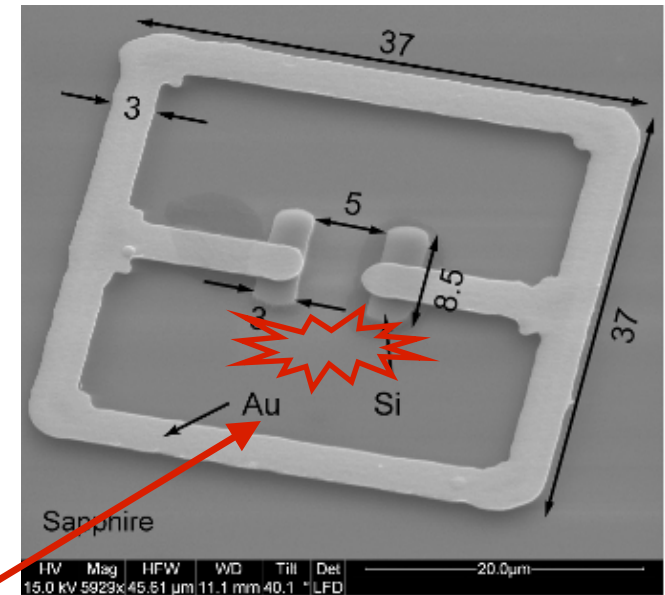
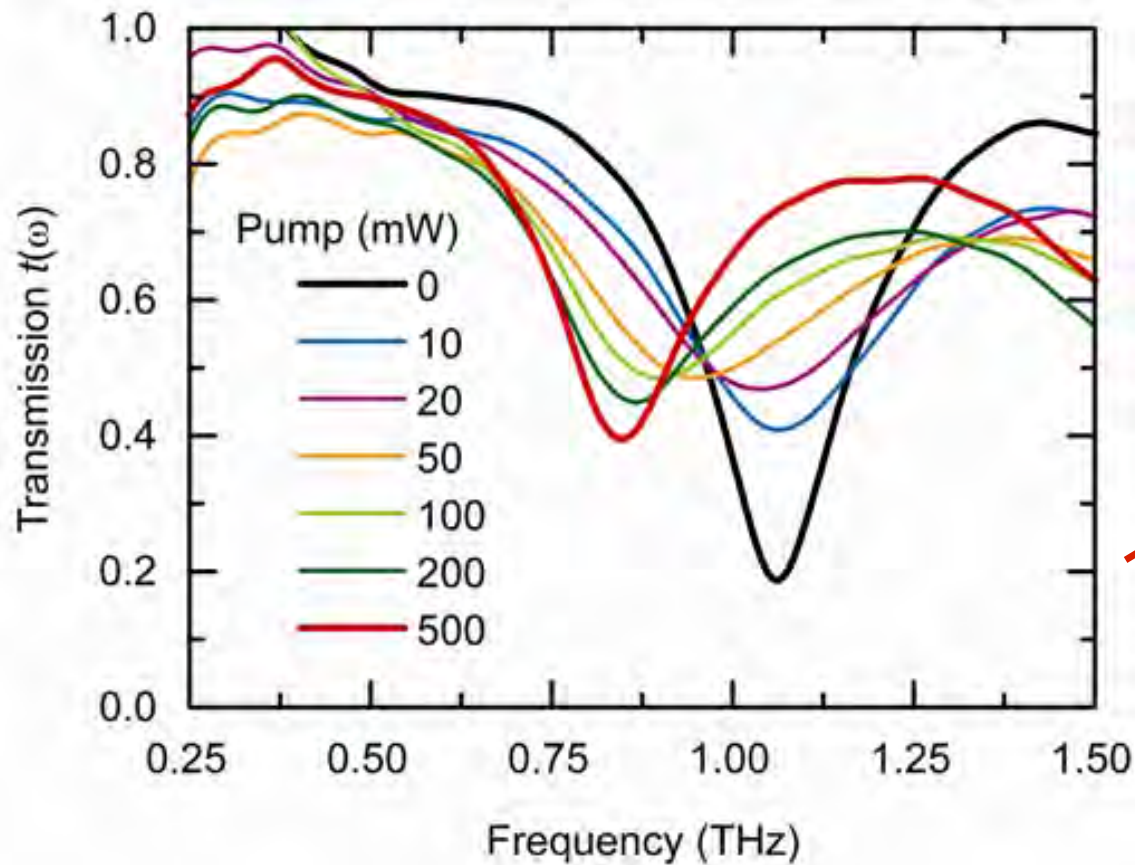


photo-excitation



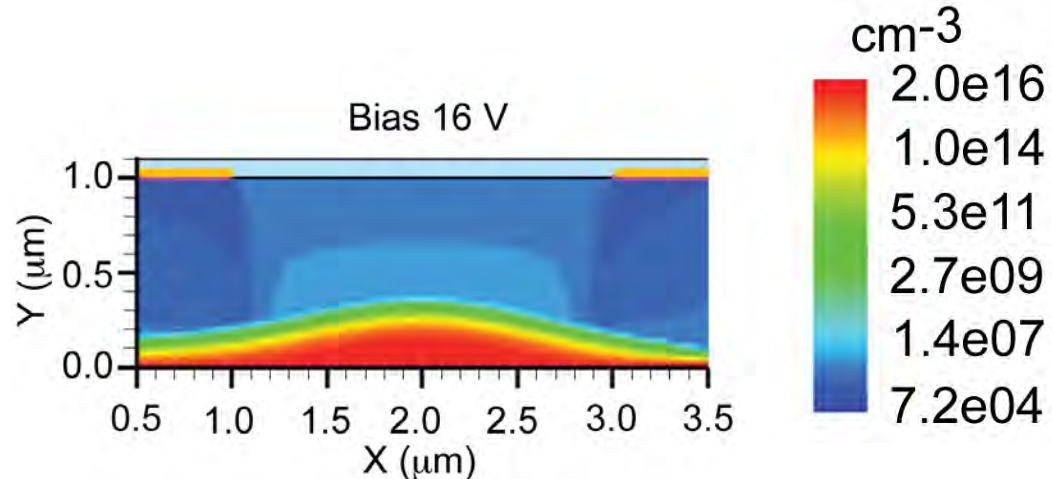
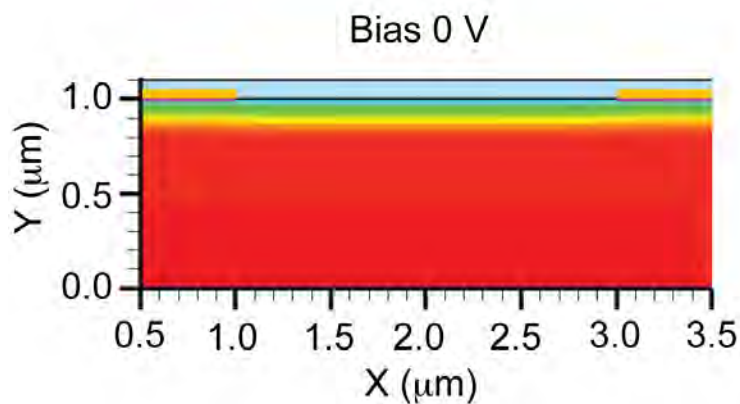
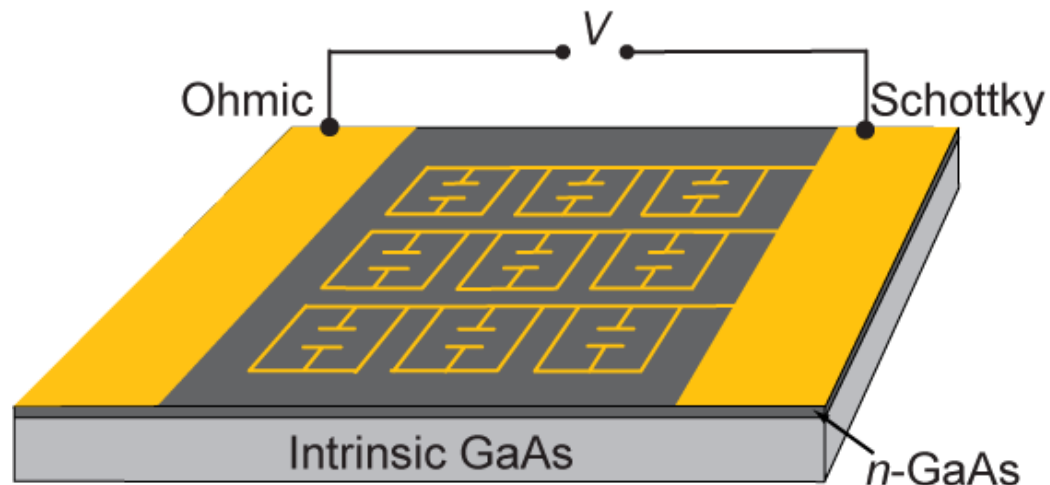
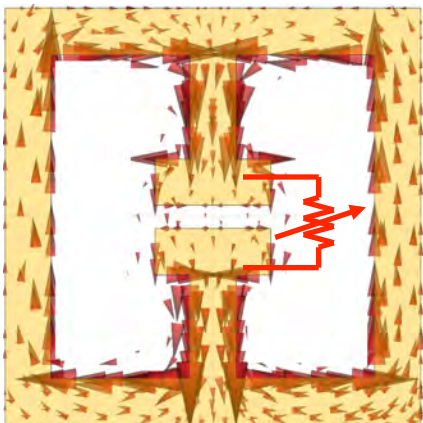


# Optically Frequency Tunable THz Metamaterials



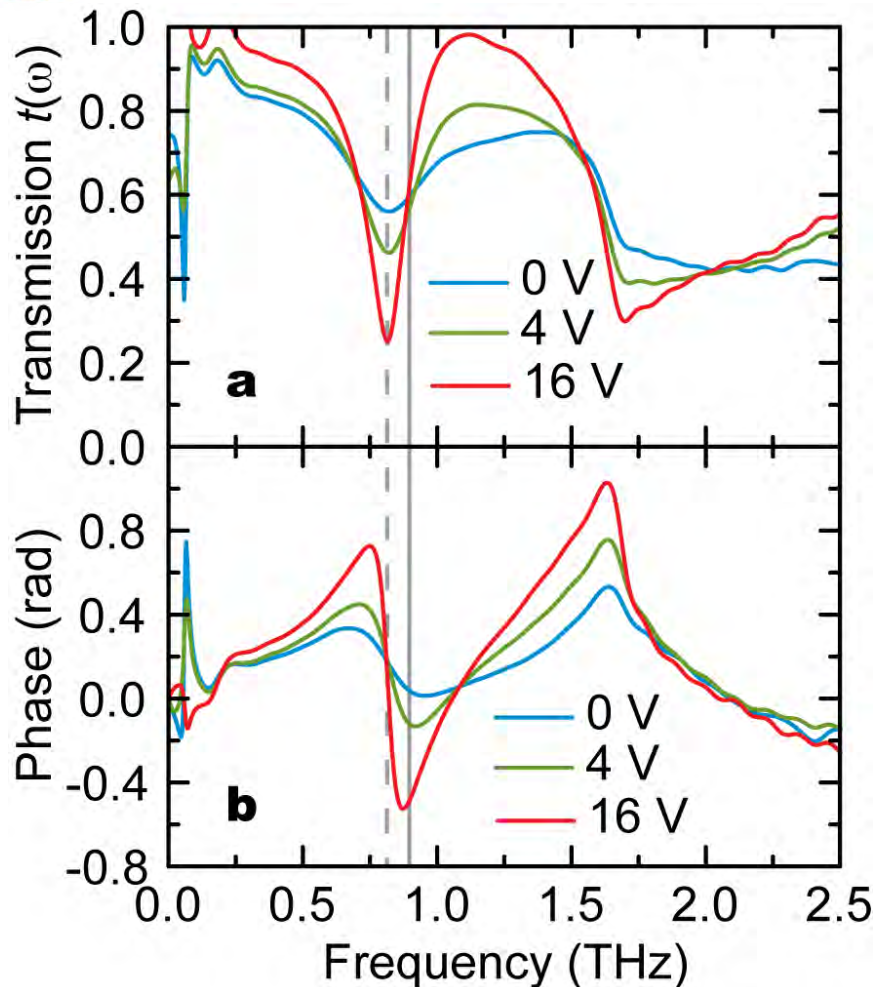


# Electrically Switchable THz Metamaterials





# Amplitude and Phase Modulations



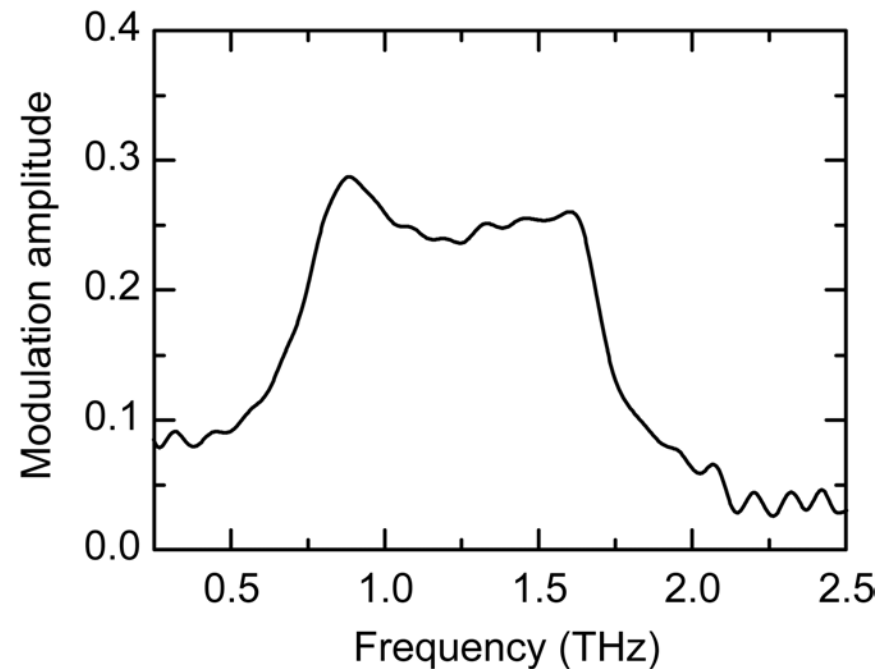
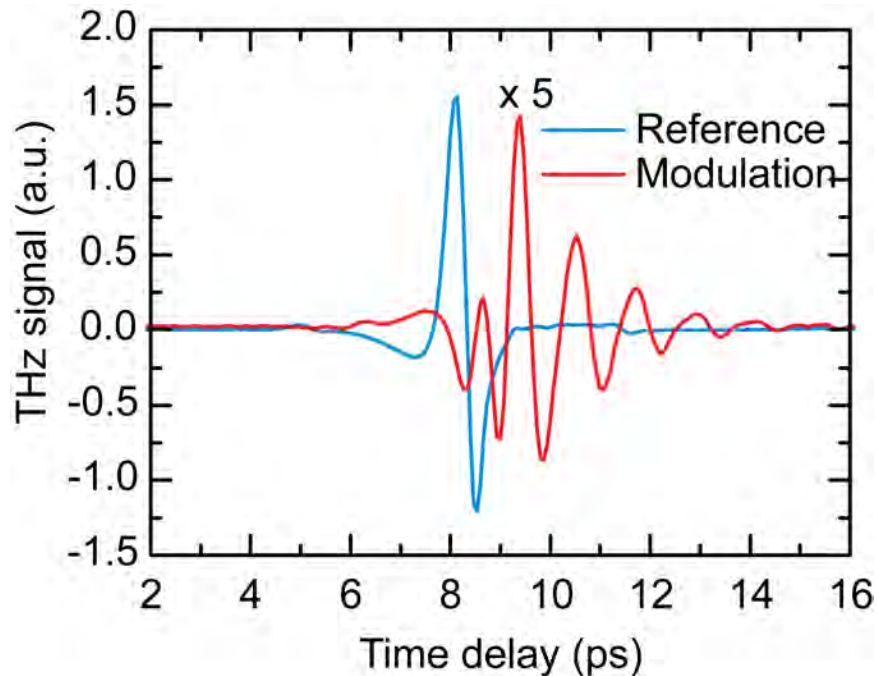
- Power modulation depth:  
 $M = (T_{0V} - T_{16V}) / T_{0V} = 80\%$ ,  
or amplitude modulation depth 55%
- Phase modulation  $\Delta\phi = \pi/6$
- Amplitude and phase modulations are correlated
- In THz-TDS, both amplitude and phase contribute to the modulation signal – **broadband modulation**

$$|\Delta\tilde{t}(\omega)| = \left| t_{V1}(\omega)e^{i\phi_{V1}(\omega)} - t_{V2}(\omega)e^{i\phi_{V2}(\omega)} \right|$$





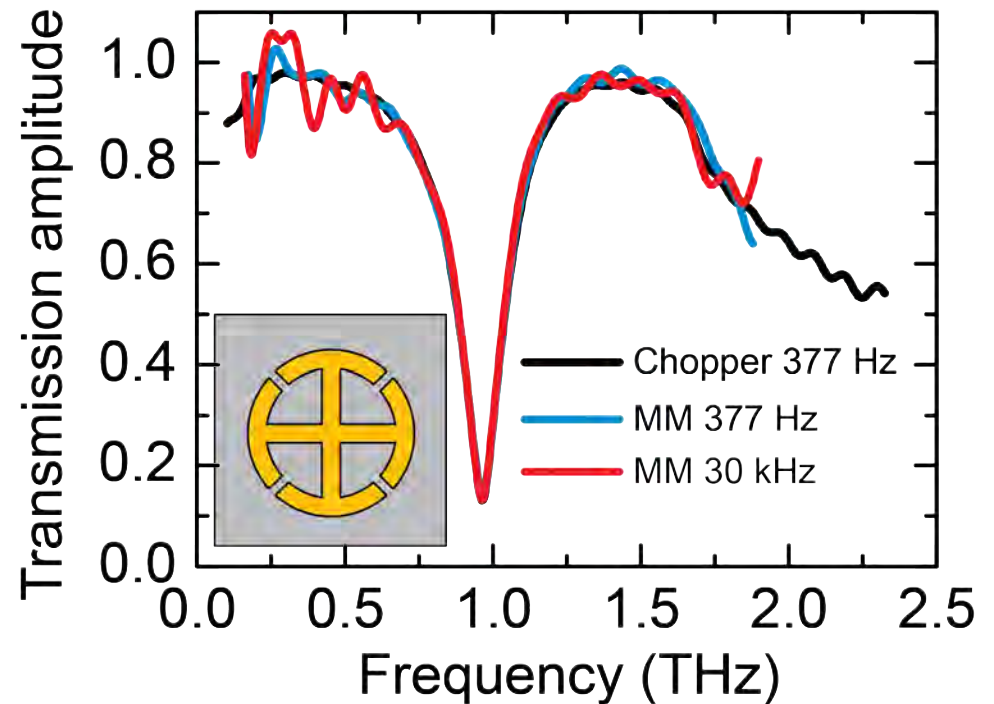
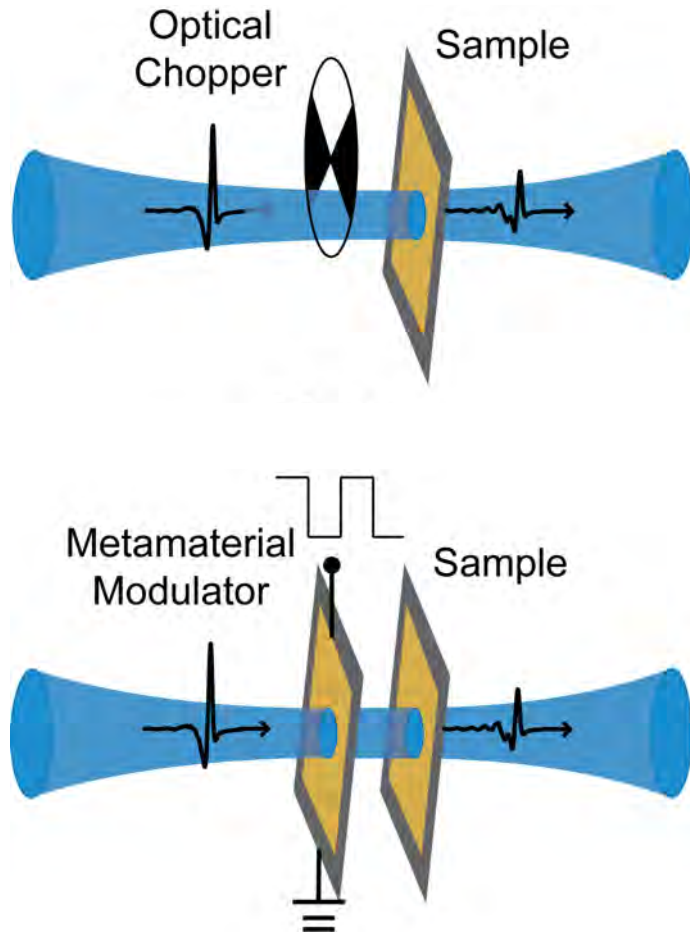
# Broaden the Modulation Bandwidth



**Bandwidth:** roughly between the two resonances

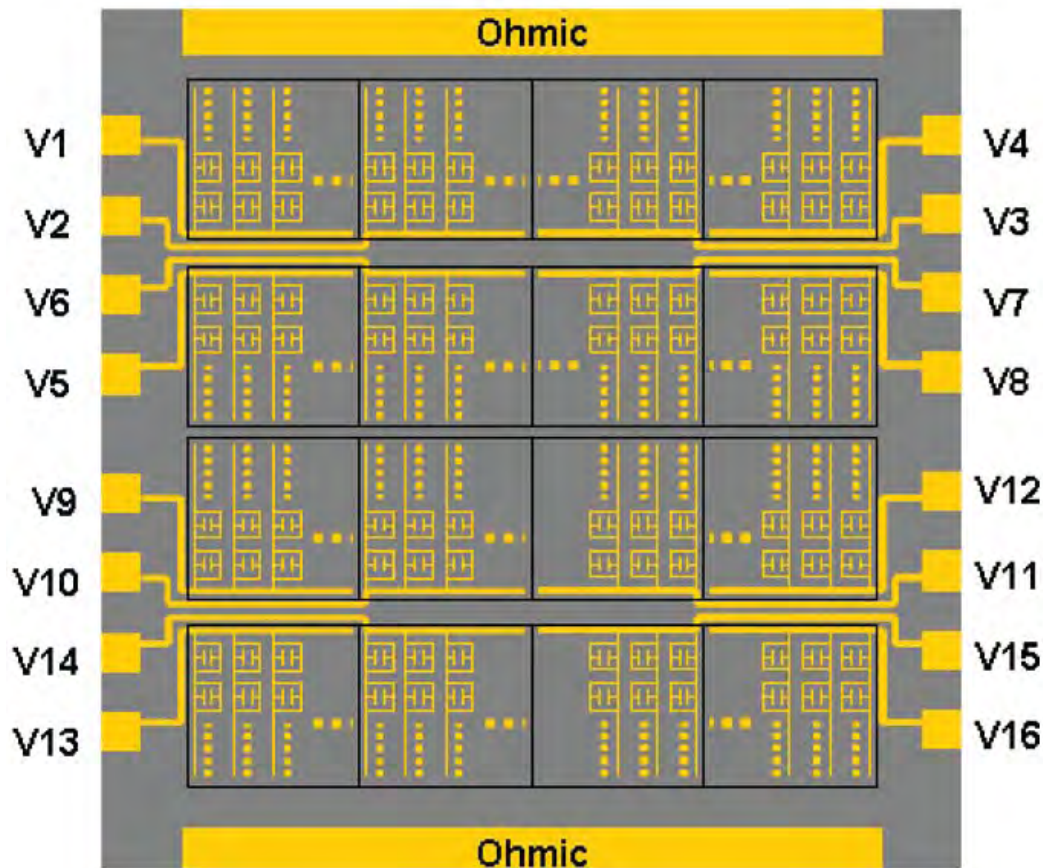


# Serving as the Optical Chopper in THz-TDS





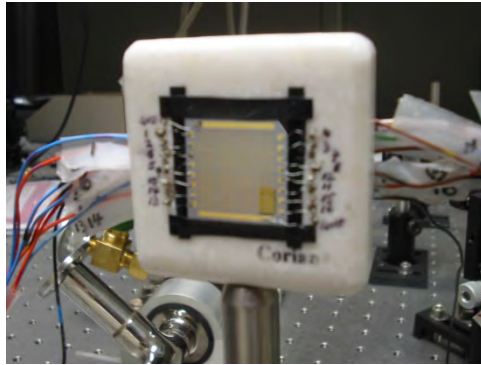
# THz Metamaterial Spatial Light Modulator



4 × 4 pixels, each pixel is independently controlled by voltage bias



# THz Metamaterial Spatial Light Modulator



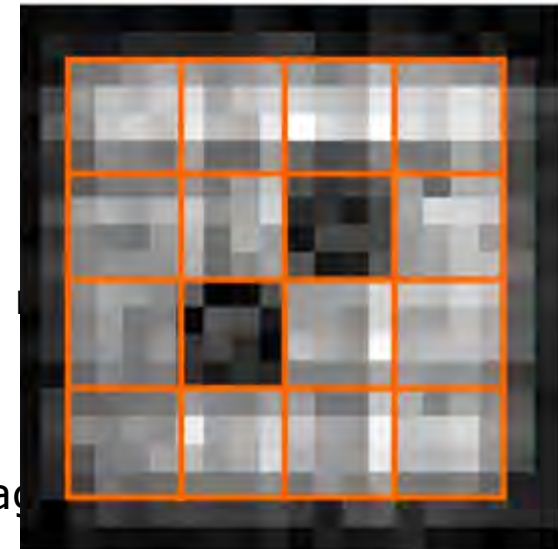
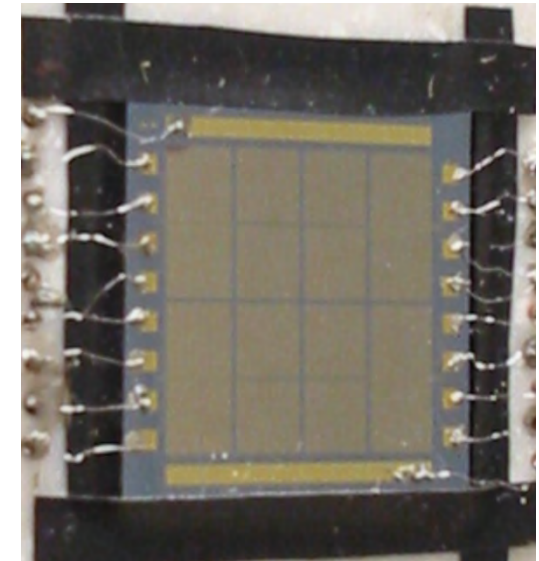
THz transmitter  
(fiber-coupled  
PC antenna)

THz spatial  
modulator

metal  
aperture

V1-V16 / GND  
connecting to  
external circuit

automated  
translation stage

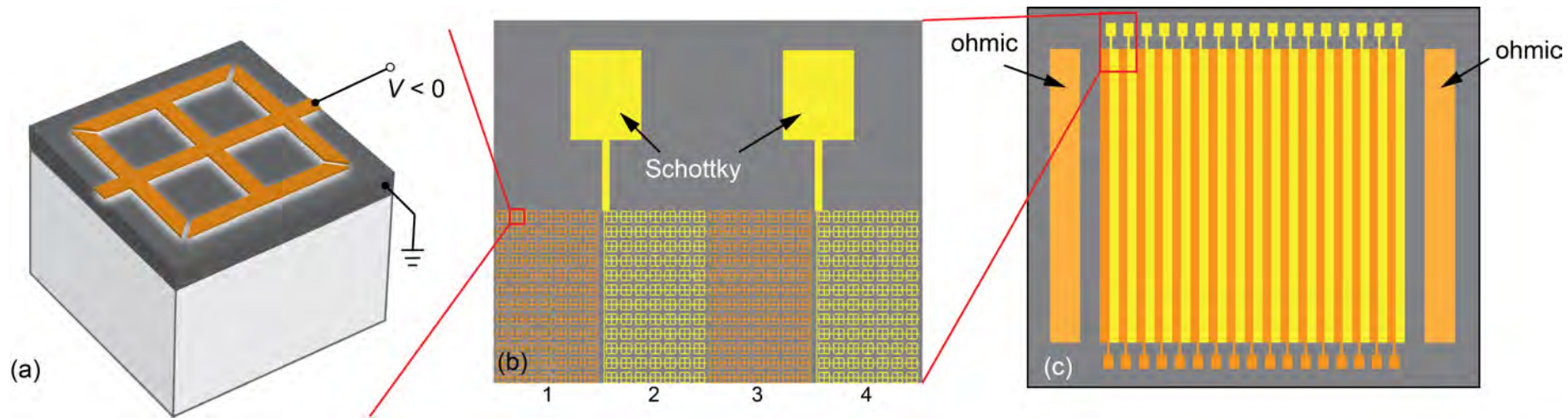


$f = 6\text{cm}$





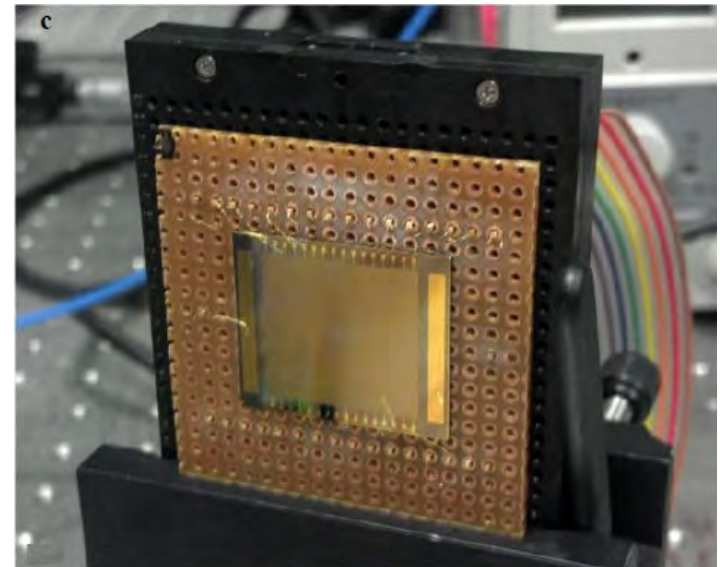
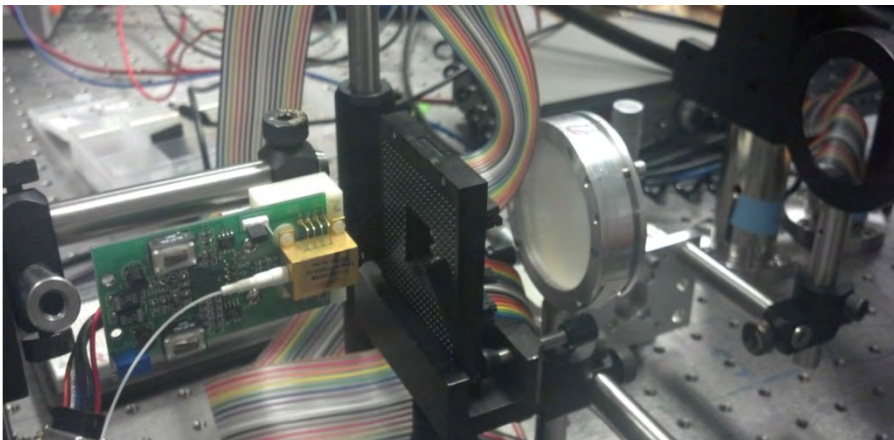
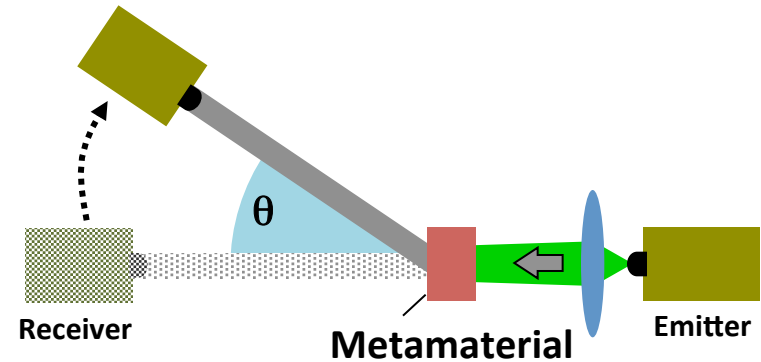
# Active Metamaterial Gratings





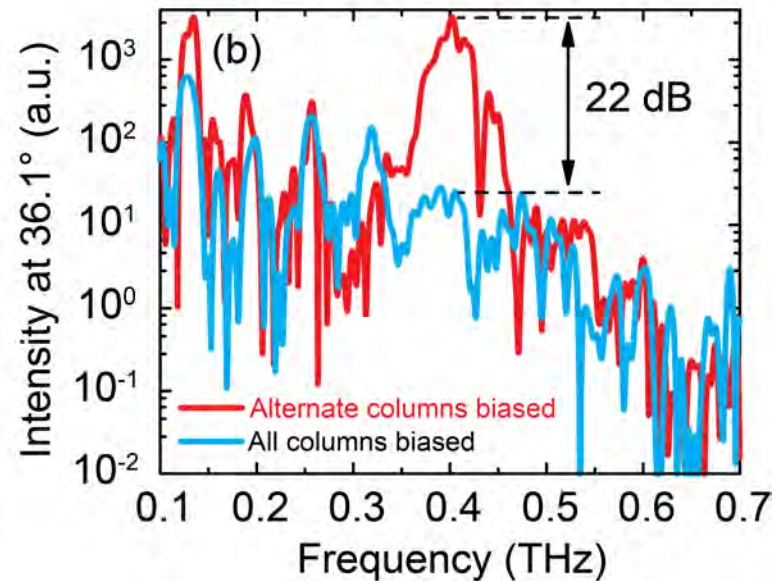
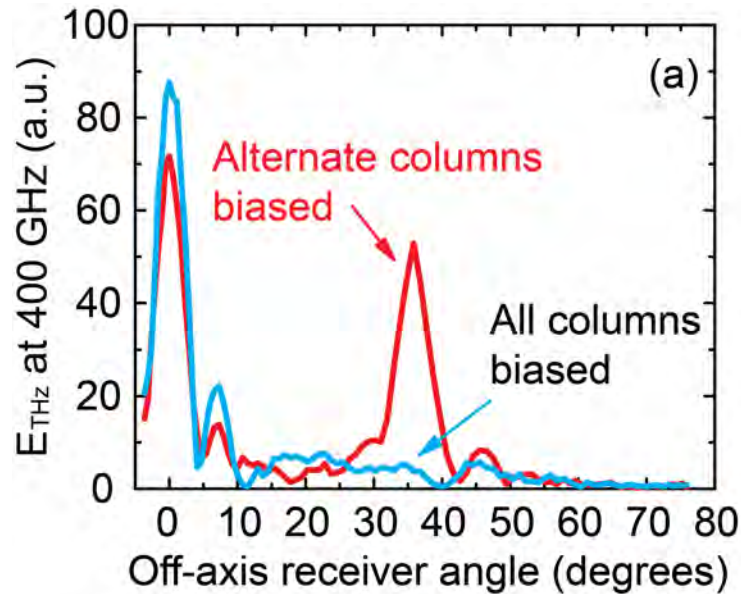
# Active Metamaterial Gratings -- Experiment

- ❑ Broadband THz system
- ❑ Collimated beam incident on metamaterial surface
- ❑ Detect transmitted beam at different angles

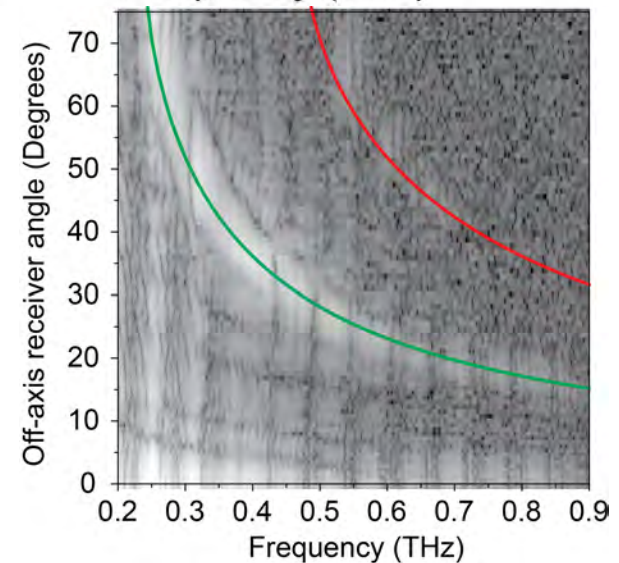




# Active Metamaterial Gratings -- Results



- Switchable grating diffraction
- 22 dB modulation depth
- Broadband operation
- Background-free in principle





# Summary of Active Metamaterials/Metasurfaces

- Switchable and frequency tunable resonant response in single-layer metasurfaces by active material integration and external excitation

Strontium Titanate Substrate

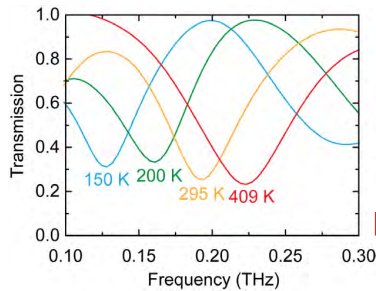
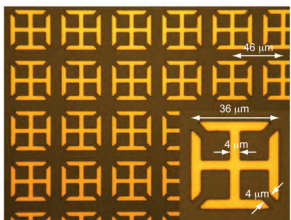
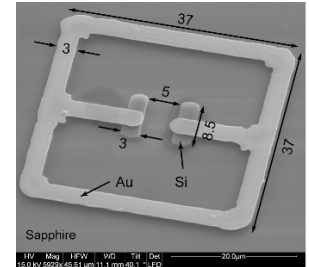
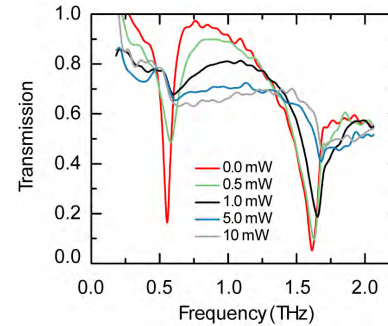
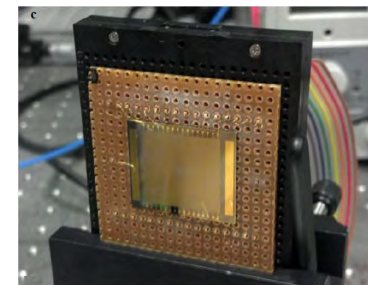
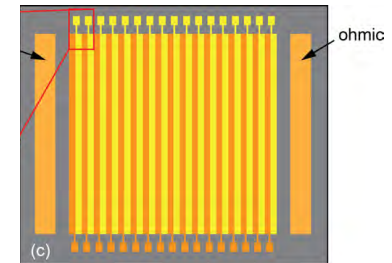
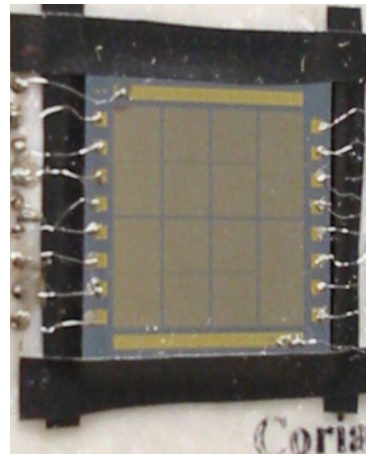
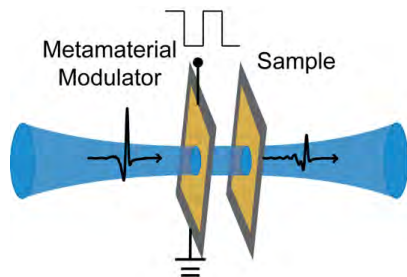
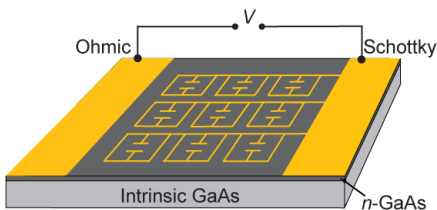


photo-excitation



- Electrically switchable metasurface as THz signal modulator for imaging and communication







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